QRW010/025/035/040 Series Modules; DC-DC Converter Power Modules

36-75Vdc Input; 1.0 to 12.0Vdc, 10A to 40A

RoHS Compliant

Applications

- Enterprise Networks
- Wireless Networks
- Access and Optical Network Equipment
- Enterprise Networks
- Latest generation IC's (DSP, FPGA, ASIC) and Microprocessor-powered applications.

Options

- Positive Remote On/Off logic
- Case ground pin (-H Base plate version)
- Auto restart after fault shutdown

Features

- Compliant to RoHS Directive 2011/65/EU and amended Directive (EU) 2015/863.(-Zversions)
- Compliant to REACH Directive (EC) No 1907/2006
- Delivers up to 40A output current
- Ultra High efficiency – 91% at 3.3V full load
- Industry standard DOSA Compliant Quarter brick: 57.9 mm x 36.8 mm x 9.5 mm (2.28 in x 1.45 in x 0.375 in)
- Improved Thermal Performance: 23A at 70ºC at 1m/s (200LFM) for 3.3Vo
- High power density: 100W/in^3
- Low output ripple and noise
- Low output voltages down to 1V: Supports migration to future IC and microprocessor supply voltages
- 2:1 input voltage
- Remote Sense
- Remote On/Off
- Constant switching frequency
- Output overvoltage and Overcurrent protection
- Overtemperature protection
- Adjustable output voltage (+10% / -20%)
- Meets the voltage isolation requirements for ETSI 300-132-2 and complies with and is licensed for Basic Insulation rating per EN62368-1
- ANSI/UL* 62368-1 and CAN/CSA† C22.2 No. 62368-1 Recognized, DIN VDE‡ 0868-1/A11:2017 (EN62368-1:2014/A11:2017)
- CE mark meets 2014/35/EU directive§
- ISO* 9001 certified manufacturing facilities

Description

The QRW-series dc-dc converters are a new generation of DC/DC power modules designed for optimum efficiency and power density. The QRW series provide up to 40A output current in an industry standard quarter brick, which makes it an ideal choice for small space, high current and low voltage applications. The converter uses synchronous rectification technology and innovative packaging techniques to achieve ultra high efficiency reaching 91% at 3.3V full load. Thanks to the ultra high efficiency of this converter, the power dissipation is such that for most applications a heat sink is not required. In addition, the QRW-series supports future migration of semiconductor and microprocessor supply voltages down to 1.0V.

* ISO is a registered trademark of the International Organization of Standards
** *UL* is a registered trademark of Underwriters Laboratories, Inc.
† *CSA* is a registered trademark of Canadian Standards Association.
‡ *VDE* is a trademark of Verband Deutscher Elektrotechniker e.V.
§ This product is intended for integration into end-use equipment. All of the required procedures of end-use equipment should be followed.

Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only, functional operation of the device is not implied at these or any other conditions in excess of those given in the operations sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect the device reliabiltiy.

Parameter	Device	Symbol	Min	Max	Unit
Input Voltage:Continuous Transient (100ms)	All	VI VI, trans	— —	80 100	Vdc Vdc
Operating Ambient Temperature (See Thermal Considerations section)	All	TA	–40	85	°C
Storage Temperature	All	Tstg	–55	125	°C
I/O Isolation Voltage (100% factory Hi-Pot tested) When using optional case ground pin (option 7)	—	—	1500 700	Vdc Vdc	

Electrical Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions.

Parameter	Device	Symbol	Min	Typ	Max	Unit
Operating Input Voltage	All	VIN	36	48	75	Vdc
Maximum Input Current (VI = 0 V to 75 V; IO = IO, max)	All		—	—	4.5	Adc
Inrush Transient	All	I^2t			1	A^2s
Input Reflected Ripple Current, peak-peak (5 Hz to 20 MHz, 12 µH source impedance See Test configuration section)	All			16		mAp-p
Input Ripple Rejection (120 Hz)	All			60		dB

CAUTION: This power module is not internally fused. An input line fuse must always be used.

This power module can be used in a wide variety of applications, ranging from simple stand-alone operation to an integrated part of a sophisticated power architecture. To preserve maximum flexibility, internal fusing is not included; however, to achieve maximum safety and system protection, always use an input line fuse. The safety agencies require a normal-blow fuse with a maximum rating of 10 A (see Safety Considerations section). Based on the information provided in this data sheet on inrush energy and maximum dc input current, the same type of fuse with a lower rating can be used. Refer to the fuse manufacturer's data for further information.

Electrical Specifications (continued)

Output Specifications for the QRW040A0S1R0 (Vo = 1.0Vdc)

Parameter	Device	Symbol	Min	Typ	Max	Unit
Output Voltage Set Point (VI = 48 Vdc; IO = IO, min to IO, max, TA = 25 °C)	P	Vo	0.99	1.0	1.01	Vdc
Output Voltage (Over all operating input voltage, resistive load, and temperature conditions at steady state until end of life.)	P	Vo	0.98	—	1.02	Vdc
Output Regulation: Line (VI = VI, min to VI, max) Load (IO = IO, min to IO, max) Temperature (TA = TA, min to TA, max)	P	 — — —	 — — —	 0.1 0.1 15	 0.3 0.3 50	 %, VO, set %, VO, set mV
Output Ripple and Noise RMS (5 Hz to 20 MHz bandwidth) Peak-to-peak (5 Hz to 20 MHz bandwidth)	P		 — —	 — —	 30 80	 mVrms mVp-p
External Load Capacitance				—	25,000	µF
Output Current (Vo =90% of VO, nom.)	P	IO	0.0	—	40	Adc
Output Current-limit Inception (VO = 90% of VO, set)	P	IO, lim	—	49	—	Adc
Output Short-circuit Current (Average)VO = 0.25 V	Latched off					
Efficiency (VI = VIN, nom; IO = IO, max), TA = 25 °C		η	—	83	—	%
Switching Frequency	All	fSW	—	300	—	kHz
Dynamic Response (DIO/Dt = 1 A/10 µs, VI = 48 V, TA = 25 °C); tested with a 220 µF aluminium and a 1.0 µf ceramic capacitor across the load.): Load Change from IO = 50% to 75% of IO, max: Peak Deviation Settling Time (VO < 10% of peak deviation) Load Change from IO = 50% to 25% of IO, max : Peak Deviation Settling Time (VO < 10% of peak deviation)				 160 200 180 200		 mV µs mV µs

Isolation Specifications

Parameter	Symbol	Min	Typ	Max	Unit
Isolation Capacitance	Ciso	—	5600	—	PF
Isolation Resistance	Riso	10	—	—	MΩ

General Specifications

Parameter	Min	Typ	Max	Unit
Calculated MTBF (Io = 80% of Io, max Ta = 40 °C		TBD		Hours
Weight	—	37(1.31)	—	g (oz.)

Feature Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

Parameter	Symbol	Min	Typ	Max	Unit
Remote On/Off Signal Interface*					
(VI = 0 V to 75 V; open collector or equivalent compatible; signal referenced to VI(–) terminal; see Figure 52 and Feature Descriptions.):					
Preferred Logic:					
Logic Low—Module On					
Logic High—Module Off					
Optional Logic:					
Logic Low—Module Off					
Logic High—Module On					
Logic Low:					
At Ion/off = 1.0 mA					
At Von/off = 0.0 V	Von/off	0	—	1.2	V
Logic High:	Ion/off	—	—	1.0	mA
At Ion/off = 0.0 µA					
Leakage Current	Von/off	—	—	15	V
Turn-on Time; see Typical Start-up Curve(IO = IO max;	Ion/off	—	—	50	µA
Vo within ±1% of steady state)			2	4	ms
Output Voltage Adjustment					
(See Feature Descriptions):					
Output Voltage Remote-sense Range	—	—	—	10	%VO,rated
Output Voltage Set-point Adjustment Range (trim)	—	80	—	110	%V0,nom
Output Overvoltage Protection	VO, ovsd	1.25	—	1.5	V
Overtemperature Protection (IO = IO, max)	Tref1	—	127	—	°C

Characteristic Curves

The following figures provide typical characteristics curves for the QRW040A0S1R0 (VO = 1.0 V) module at room temperature (TA = 25 °C).The figures are identical for both on/off configurations.

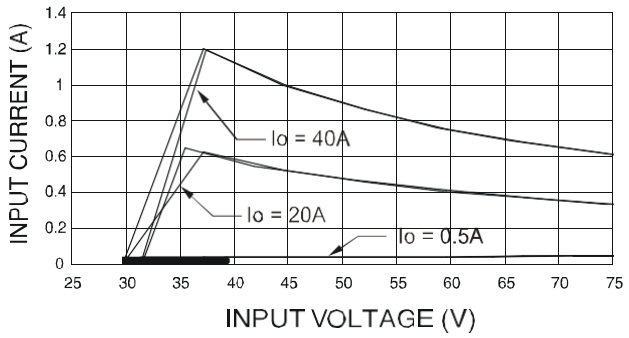


Figure 1. Input Voltage and Current Characteristics.

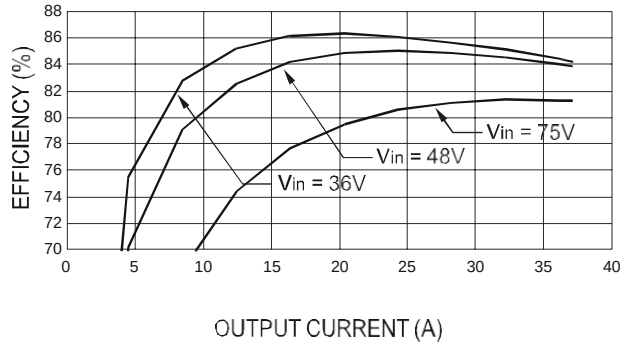


Figure 2. Converter Efficiency vs. Output Current.

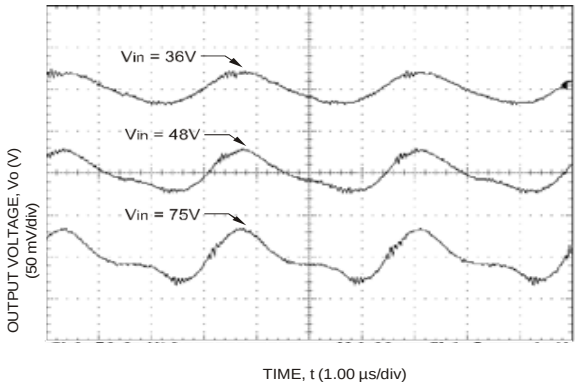
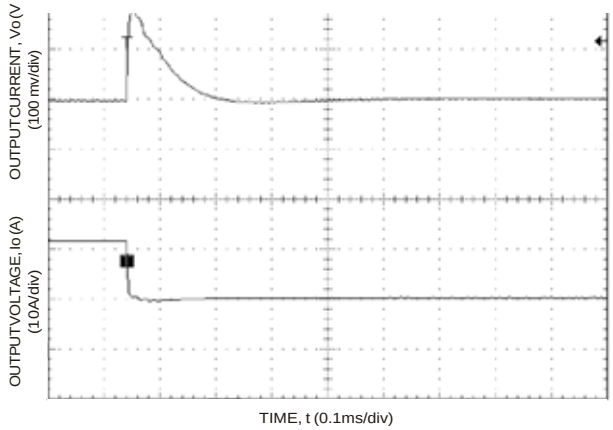


Figure 3. Output Ripple Voltage (IO = IO, max).



Tested with a 220µF aluminium and a 1.0µF ceramic capacitor across the load.

Figure 4. Transient Response to Step decrease in Load from 50% to 25% of Full Load (VI = 48 Vdc).

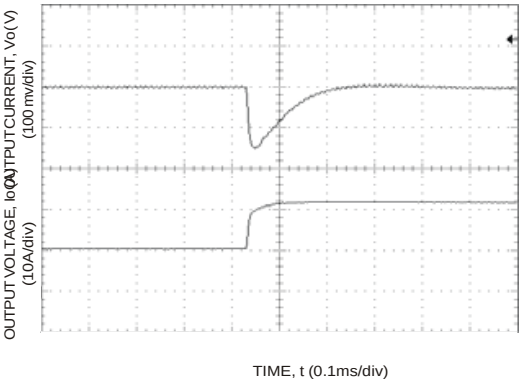


Figure 5. Transient Response to Step Increase in Load from 50% to 75% of Full Load (VI = 48 Vdc).

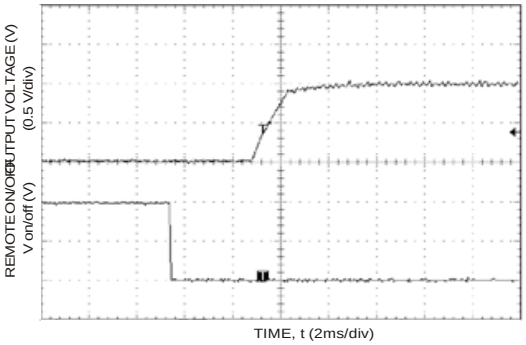


Figure 6. Start-up from Remote On/Off (IO = IO, max).

Electrical Specifications (continued)

Output Specifications for the QRW040AP (Vo = 1.2Vdc)

Parameter	Device	Symbol	Min	Typ	Max	Unit
Output Voltage Set Point (VI = 48 Vdc; IO = IO, min to IO, max, TA = 25 °C)	P	Vo	1.18	1.2	1.22	Vdc
Output Voltage (Over all operating input voltage, resistive load, and temperature conditions at steady state until end of life.)	P	Vo	1.16	—	1.24	Vdc
Output Regulation: Line (VI = VI, min to VI, max) Load (IO = IO, min to IO, max) Temperature (TA = TA, min to TA, max)	P	 — — —	 — — —	 0.05 0.05 15	 0.3 0.3 50	 %, VO, set %, VO, set mV
Output Ripple and Noise RMS (5 Hz to 20 MHz bandwidth) Peak-to-peak (5 Hz to 20 MHz bandwidth)	P		 — —	 — —	 30 80	 mVrms mVp-p
External Load Capacitance				—	25,000	µF
Output Current (Vo =90% of VO, nom.)	P	IO	0.0	—	40	Adc
Output Current-limit Inception (VO = 90% of VO, set)	P	IO, lim	—	45	—	Adc
Output Short-circuit Current (Average)VO = 0.25 V	Latched off					
Efficiency (VI = VIN, nom; IO = IO, max), TA = 25 °C		η	—	85	—	%
Switching Frequency	All	fSW	—	300	—	kHz
Dynamic Response (DIO/Dt = 1 A/10 µs, VI = 48 V, TA = 25 °C); tested with a 220 µF aluminium and a 1.0 µf ceramic capacitor across the load.): Load Change from IO = 50% to 75% of IO, max: Peak Deviation Settling Time (VO < 10% of peak deviation) Load Change from IO = 50% to 25% of IO, max : Peak Deviation Settling Time (VO < 10% of peak deviation)				 120 200 120 200		 mV µs mV µs

Isolation Specifications

Parameter	Symbol	Min	Typ	Max	Unit
Isolation Capacitance	Ciso	—	5600	—	PF
Isolation Resistance	Riso	10	—	—	MΩ

General Specifications

Parameter	Min	Typ	Max	Unit
Calculated MTBF (Io = 80% of Io, max Ta = 40 °C), Issue 1, M1, C1		1,271,000		Hours
Weight	—	37(1.31)	—	g (oz.)

Feature Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

Parameter	Symbol	Min	Typ	Max	Unit
Remote On/Off Signal Interface*					
(VI = 0 V to 75 V; open collector or equivalent compatible; signal referenced to VI(–) terminal; see Figure 52 and Feature Descriptions.):					
Preferred Logic:					
Logic Low—Module On					
Logic High—Module Off					
Optional Logic:					
Logic Low—Module Off					
Logic High—Module On					
Logic Low:					
At Ion/off = 1.0 mA					
At Von/off = 0.0 V	Von/off	0	—	1.2	V
Logic High:	Ion/off	—	—	1.0	mA
At Ion/off = 0.0 µA					
Leakage Current	Von/off	—	—	15	V
Turn-on Time; see Typical Start-up Curve(IO = IO max;	Ion/off	—	—	50	µA
Vo within ±1% of steady state)			2	4	ms
Output Voltage Adjustment					
(See Feature Descriptions):					
Output Voltage Remote-sense Range	—	—	—	10	%VO,rated
Output Voltage Set-point Adjustment Range (trim)	—	80	—	110	%V0,nom
Output Overvoltage Protection	VO, ovsd	1.42	—	1.58	V
Overtemperature Protection (IO = IO, max)	Tref1	—	127	—	°C

* A Minimum OFF Period of 1 sec is recommended.

Characteristic Curves

The following figures provide typical characteristics curves for the QRW040A0P (VO = 1.2 V) module at room temperature (TA = 25 °C)

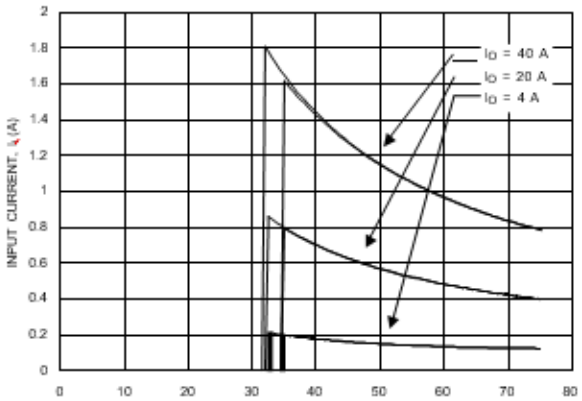


Figure 7. Input Voltage and Current Characteristics.

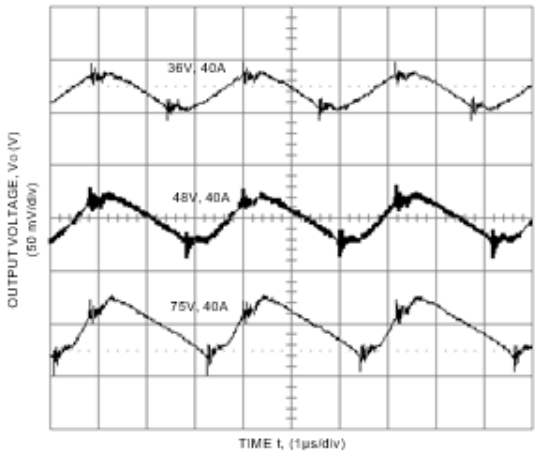


Figure 9. Output Ripple Voltage (IO = IO, max).

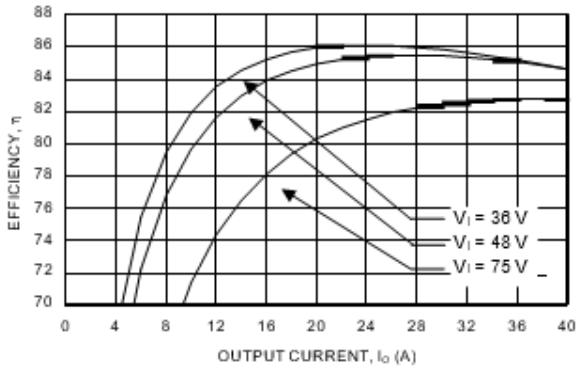
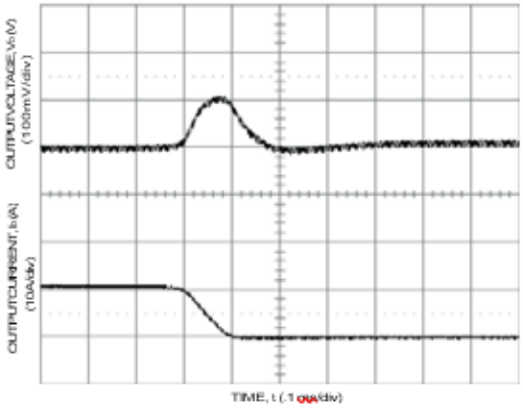
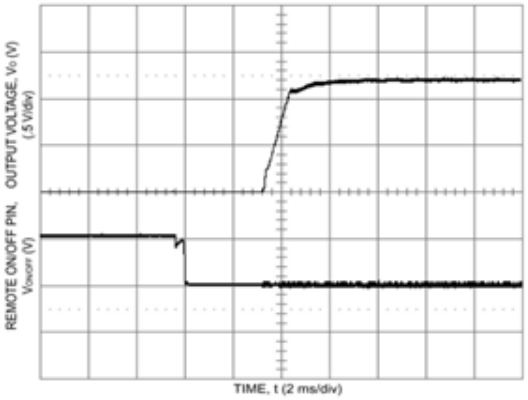


Figure 8. Converter Efficiency vs. Output Current.



Tested with a 220μF aluminium and a 1.0μF ceramic capacitor across the load.

Figure 10. Transient Response to Step Decrease in Load from 50% to 25% of Full Load (VI = 48 Vdc).



Tested with a 10μF aluminium and a 1.0μF tantalum capacitor across the load.

Figure 12. Start-up from Remote On/Off (IO = IO, max).

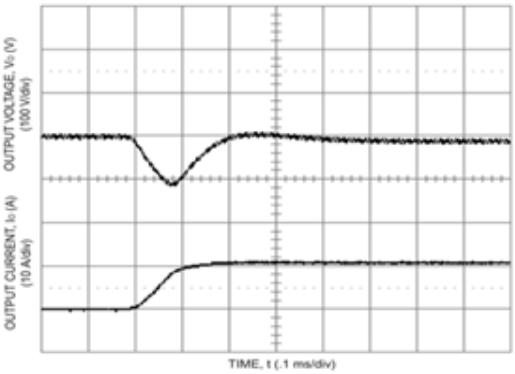


Figure 11. Transient Response to Step Increase in Load from 50% to 75% of Full Load (VI = 48 Vdc).

Electrical Specifications (continued)

Output Specifications for the QRW040AOM (Vo = 1.5Vdc)

Parameter	Device	Symbol	Min	Typ	Max	Unit
Output Voltage Set Point (VI = 48 Vdc; IO = IO, min to IO, max, TA = 25 °C)	M	Vo	1.47	1.5	1.52	Vdc
Output Voltage (Over all operating input voltage, resistive load, and temperature conditions at steady state until end of life.)	M	Vo	1.45	—	1.55	Vdc
Output Regulation: Line (VI = VI, min to VI, max) Load (IO = IO, min to IO, max) Temperature (TA = TA, min to TA, max)	M	 — — —	 — — —	 0.05 0.05 15	 0.2 0.2 50	 %, VO, set %, VO, set mV
Output Ripple and Noise RMS (5 Hz to 20 MHz bandwidth) Peak-to-peak (5 Hz to 20 MHz bandwidth)	M		 — —	 — —	 20 100	 mVrms mVp-p
External Load Capacitance				—	25,000	µF
Output Current (Vo =90% of VO, nom.)	M	IO	0.0	—	40	Adc
Output Current-limit Inception (VO = 90% of VO, set)	M	IO, lim	—	47	—	Adc
Output Short-circuit Current (Average)VO = 0.25 V	Latched off					
Efficiency (VI = VIN, nom; IO = IO, max), TA = 25 °C		η	—	86.5	—	%
Switching Frequency	All	fSW	—	300	—	kHz
Dynamic Response (DIO/Dt = 1 A/10 µs, VI = 48 V, TA = 25 °C); tested with a 220 µF aluminium and a 1.0 µf ceramic capacitor across the load.): Load Change from IO = 50% to 75% of IO, max: Peak Deviation Settling Time (VO < 10% of peak deviation) Load Change from IO = 50% to 25% of IO, max : Peak Deviation Settling Time (VO < 10% of peak deviation)				 120 200 120 200		 mV µs mV µs

Isolation Specifications

Parameter	Symbol	Min	Typ	Max	Unit
Isolation Capacitance	Ciso	—	5600	—	PF
Isolation Resistance	Riso	10	—	—	MΩ

General Specifications

Parameter	Min	Typ	Max	Unit
Calculated MTBF (Io = 80% of Io, max Ta = 40 °C), Issue 1, M1, C1		1,548,000		Hours
Weight	—	38(1.54)	—	g (oz.)

Feature Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

Parameter	Symbol	Min	Typ	Max	Unit
Remote On/Off Signal Interface*					
(VI = 0 V to 75 V; open collector or equivalent compatible; signal referenced to VI(–) terminal; see Figure 52 and Feature Descriptions.):					
Preferred Logic:					
Logic Low—Module On					
Logic High—Module Off					
Optional Logic:					
Logic Low—Module Off					
Logic High—Module On					
Logic Low:					
At Ion/off = 1.0 mA					
At Von/off = 0.0 V	Von/off	0	—	1.2	V
Logic High:	Ion/off	—	—	1.0	mA
At Ion/off = 0.0 µA					
Leakage Current	Von/off	—	—	15	V
Turn-on Time; see Typical Start-up Curve(IO = IO max;	Ion/off	—	—	50	µA
Vo within ±1% of steady state)			2	4	ms
Output Voltage Adjustment					
(See Feature Descriptions):					
Output Voltage Remote-sense Range	—	—	—	10	%VO,rated
Output Voltage Set-point Adjustment Range (trim)	—	80	—	110	%V0,nom
Output Overvoltage Protection	VO, ovsd	1.69	—	2.07	V
Overtemperature Protection (IO = IO, max)	Tref1	—	127	—	°C

* A Minimum OFF Period of 1 sec is recommended.

Characteristic Curves

The following figures provide typical characteristics curves for the QRW040A0M (VO = 1.5 V) module at room temperature (TA = 25 °C)

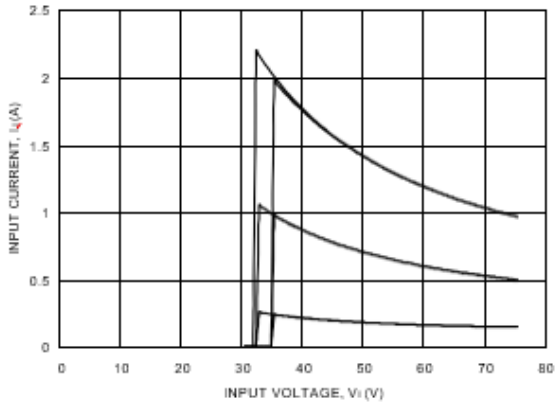


Figure 13. Input Voltage and Current Characteristics.

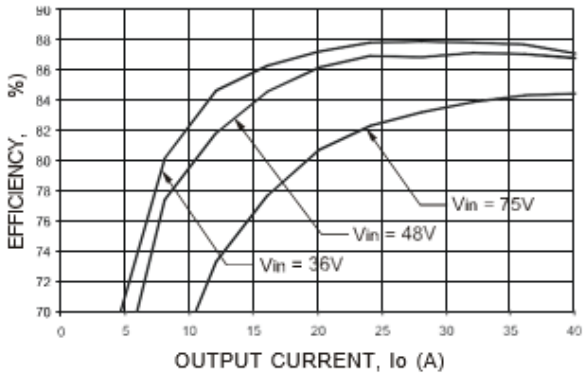


Figure 14. Converter Efficiency vs. Output Current.

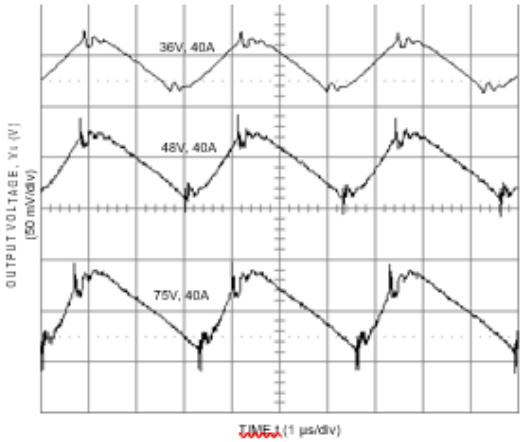
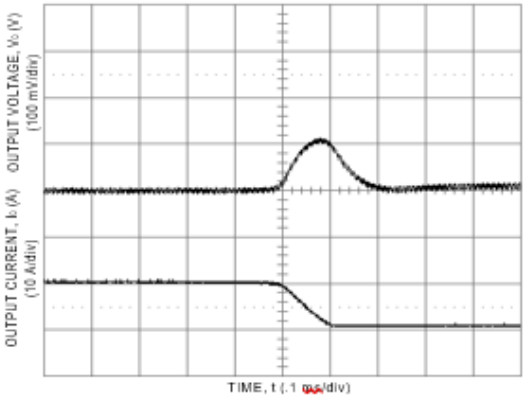


Figure 15. Output Ripple Voltage (IO = IO, max).



Tested with a 220µF aluminium and a 1.0µF ceramic capacitor across the load.

Figure 16. Transient Response to Step Decrease in Load from 50% to 25% of Full Load (VI = 48 Vdc).

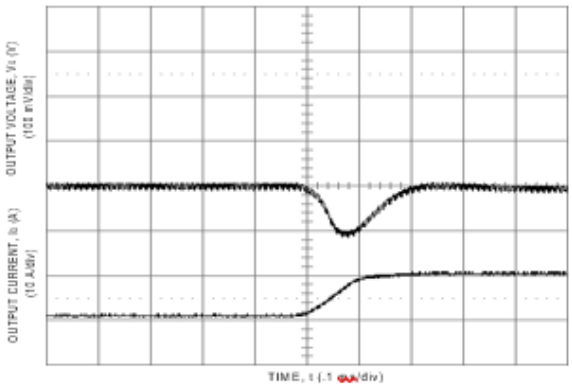
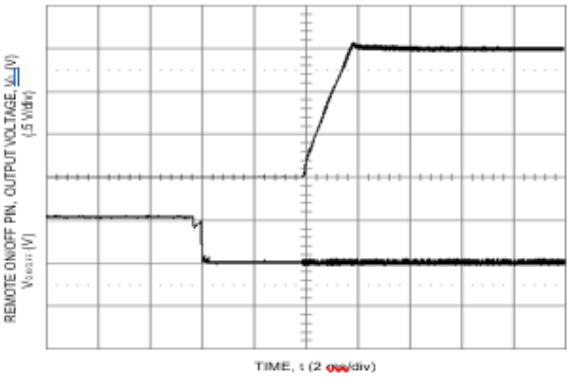


Figure 17. Transient Response to Step Increase in Load from 50% to 75% of Full Load (VI = 48 Vdc).



Tested with a 10µF aluminium and a 1.0µF tantalum capacitor across the load.

Figure 18. Start-up from Remote On/Off (IO = IO, max).

Electrical Specifications (continued)

Output Specifications for the QRW040A0Y (Vo = 1.8Vdc)

Parameter	Device	Symbol	Min	Typ	Max	Unit
Output Voltage Set Point (VI = 48 Vdc; IO = IO, min to IO, max, TA = 25 °C)	Y	Vo	1.77	1.8	1.83	Vdc
Output Voltage (Over all operating input voltage, resistive load, and temperature conditions at steady state until end of life.)	Y	Vo	1.75	—	1.85	Vdc
Output Regulation: Line (VI = VI, min to VI, max) Load (IO = IO, min to IO, max) Temperature (TA = TA, min to TA, max)	Y	 — — —	 — — —	 0.05 0.05 15	 0.2 0.2 50	 %, VO, set %, VO, set mV
Output Ripple and Noise RMS (5 Hz to 20 MHz bandwidth) Peak-to-peak (5 Hz to 20 MHz bandwidth)	Y		 — —	 — —	 35 100	 mVrms mVp-p
External Load Capacitance				—	25,000	µF
Output Current (Vo =90% of VO, nom.)	Y	IO	0.0	—	40	Adc
Output Current-limit Inception (VO = 90% of VO, set)	Y	IO, lim	—	45	—	Adc
Output Short-circuit Current (Average)VO = 0.25 V	Latched off					
Efficiency (VI = VIN, nom; IO = IO, max), TA = 25 °C		η	—	88	—	%
Switching Frequency	All	fSW	—	300	—	kHz
Dynamic Response (DIO/Dt = 1 A/10 µs, VI = 48 V, TA = 25 °C); tested with a 220 µF aluminium and a 1.0 µf ceramic capacitor across the load.): Load Change from IO = 50% to 75% of IO, max: Peak Deviation Settling Time (VO < 10% of peak deviation) Load Change from IO = 50% to 25% of IO, max : Peak Deviation Settling Time (VO < 10% of peak deviation)				 200 200 200 200		 mV µs mV µs

Isolation Specifications

Parameter	Symbol	Min	Typ	Max	Unit
Isolation Capacitance	Ciso	—	5600	—	PF
Isolation Resistance	Riso	10	—	—	MΩ

General Specifications

Parameter	Min	Typ	Max	Unit
Calculated MTBF (IO = 80% of IO, max TA = 40 °C)		TBD		Hours
Weight	—	38(1.34)	—	g (oz.)

Feature Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

Parameter	Symbol	Min	Typ	Max	Unit
Remote On/Off Signal Interface*					
(VI = 0 V to 75 V; open collector or equivalent compatible; signal referenced to VI(–) terminal; see Figure 52 and Feature Descriptions.):					
Preferred Logic:					
Logic Low—Module On					
Logic High—Module Off					
Optional Logic:					
Logic Low—Module Off					
Logic High—Module On					
Logic Low:					
At Ion/off = 1.0 mA					
At Von/off = 0.0 V	Von/off	0	—	1.2	V
Logic High:	Ion/off	—	—	1.0	mA
At Ion/off = 0.0 µA					
Leakage Current	Von/off	—	—	15	V
Turn-on Time; see Typical Start-up Curve(IO = IO max;	Ion/off	—	—	50	µA
Vo within ±1% of steady state)			2	4	ms
Output Voltage Adjustment					
(See Feature Descriptions):					
Output Voltage Remote-sense Range	—	—	—	10	%VO,rated
Output Voltage Set-point Adjustment Range (trim)	—	80	—	110	%V0,nom
Output Overvoltage Protection	VO, ovsd	2.0	—	2.5	V
Overtemperature Protection (IO = IO, max)	Tref1	—	127	—	°C

* A Minimum OFF Period of 1 sec is recommended.

Characteristic Curves

The following figures provide typical characteristics curves for the QRW040A0Y (VO = 1.8 V) module at room temperature (TA = 25 °C)

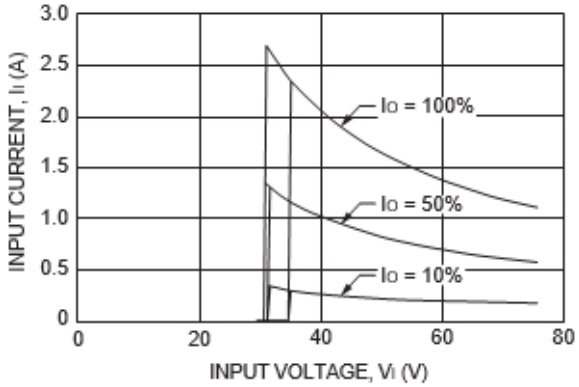


Figure 19. Input Voltage and Current Characteristics.

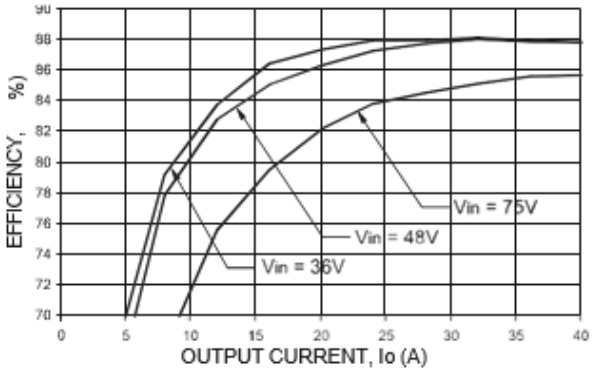


Figure 20. Converter Efficiency vs. Output Current.

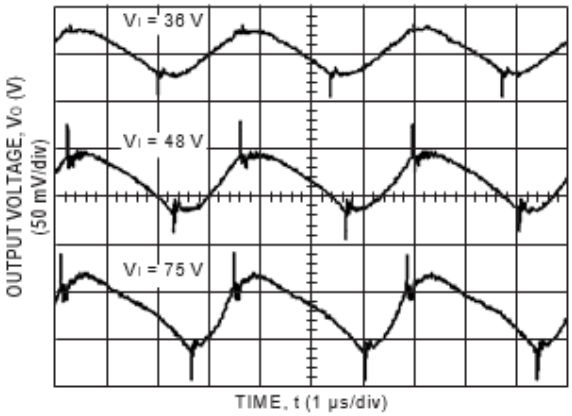
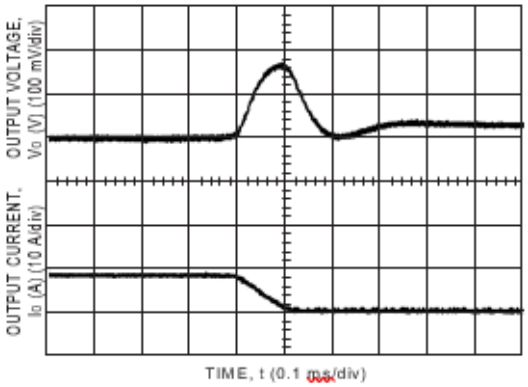


Figure 21. Output Ripple Voltage (IO = IO, max).



Tested with a 220µF aluminium and a 1.0µF ceramic capacitor across the load.

Figure 22. Transient Response to Step Decrease in Load from 50% to 25% of Full Load (VI = 48 Vdc).

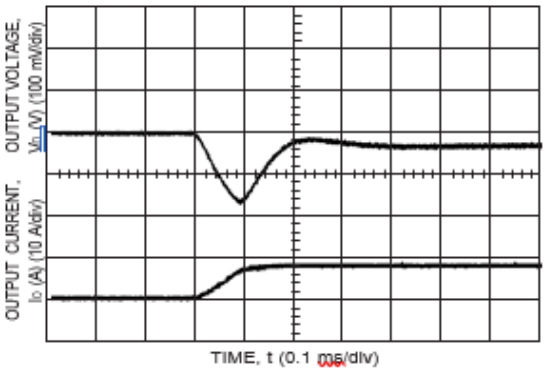
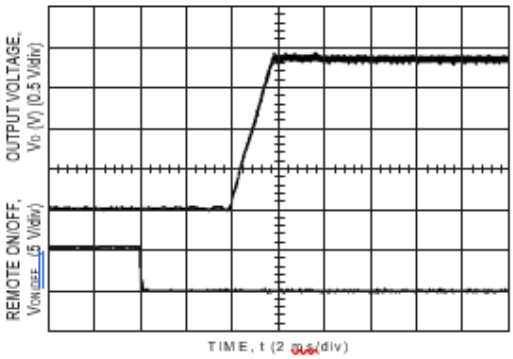


Figure 23. Transient Response to Step Increase in Load from 50% to 75% of Full Load (VI = 48 Vdc).



Tested with a 10µF aluminium and a 1.0µF tantalum capacitor across the load.

Figure 24. Start-up from Remote On/Off (IO = IO, max).

Electrical Specifications (continued)

Output Specifications for the QRW035A0G (Vo = 2.5Vdc)

Parameter	Device	Symbol	Min	Typ	Max	Unit
Output Voltage Set Point (VI = 48 Vdc; IO = IO, min to IO, max, TA = 25 °C)	G	Vo	2.47	2.5	2.53	Vdc
Output Voltage (Over all operating input voltage, resistive load, and temperature conditions at steady state until end of life.)	G	Vo	2.42	—	2.58	Vdc
Output Regulation: Line (VI = VI, min to VI, max) Load (IO = IO, min to IO, max) Temperature (TA = TA, min to TA, max)	G	 — — —	 — — —	 0.05 0.05 15	 0.2 0.2 50	 %, VO, set %, VO, set mV
Output Ripple and Noise RMS (5 Hz to 20 MHz bandwidth) Peak-to-peak (5 Hz to 20 MHz bandwidth)	G		 — —	 — —	 35 100	 mVrms mVp-p
External Load Capacitance				—	25,000	µF
Output Current (Vo =90% of VO, nom.)	G	IO	0.0	—	35	Adc
Output Current-limit Inception (VO = 90% of VO, set)	G	IO, lim	—	39	—	Adc
Output Short-circuit Current (Average)VO = 0.25 V	Latched off					
Efficiency (VI = VIN, nom; IO = IO, max), TA = 25 °C		η	—	90	—	%
Switching Frequency	All	fSW	—	300	—	kHz
Dynamic Response (DIO/Dt = 1 A/10 µs, VI = 48 V, TA = 25 °C); tested with a 220 µF aluminium and a 1.0 µf ceramic capacitor across the load.): Load Change from IO = 50% to 75% of IO, max: Peak Deviation Settling Time (VO < 10% of peak deviation) Load Change from IO = 50% to 25% of IO, max : Peak Deviation Settling Time (VO < 10% of peak deviation)				 150 200 150 200		 mV µs mV µs

Isolation Specifications

Parameter	Symbol	Min	Typ	Max	Unit
Isolation Capacitance	Ciso	—	5600	—	PF
Isolation Resistance	Riso	10	—	—	MΩ

General Specifications

Parameter	Min	Typ	Max	Unit
Calculated MTBF (IO = 80% of IO, max TA = 40 °C)		TBD		Hours
Weight	—	38(1.34)	—	g (oz.)

Feature Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

Parameter	Symbol	Min	Typ	Max	Unit
Remote On/Off Signal Interface*					
(VI = 0 V to 75 V; open collector or equivalent compatible; signal referenced to VI(–) terminal; see Figure 52 and Feature Descriptions.):					
Preferred Logic:					
Logic Low—Module On					
Logic High—Module Off					
Optional Logic:					
Logic Low—Module Off					
Logic High—Module On					
Logic Low:					
At Ion/off = 1.0 mA					
At Von/off = 0.0 V	Von/off	0	—	1.2	V
Logic High:	Ion/off	—	—	1.0	mA
At Ion/off = 0.0 µA					
Leakage Current	Von/off	—	—	15	V
Turn-on Time; see Typical Start-up Curve(IO = IO max;	Ion/off	—	—	50	µA
Vo within ±1% of steady state)			2	4	ms
Output Voltage Adjustment					
(See Feature Descriptions):					
Output Voltage Remote-sense Range	—	—	—	10	%VO,rated
Output Voltage Set-point Adjustment Range (trim)	—	80	—	110	%V0,nom
Output Overvoltage Protection	VO, ovsd	2.9	—	3.2	V
Overtemperature Protection (IO = IO, max)	Tref1	—	127	—	°C

* A Minimum OFF Period of 1 sec is recommended.

Characteristic Curves

The following figures provide typical characteristics curves for the QRW035A0G (VO = 2.5 V) module at room temperature (TA = 25 °C)

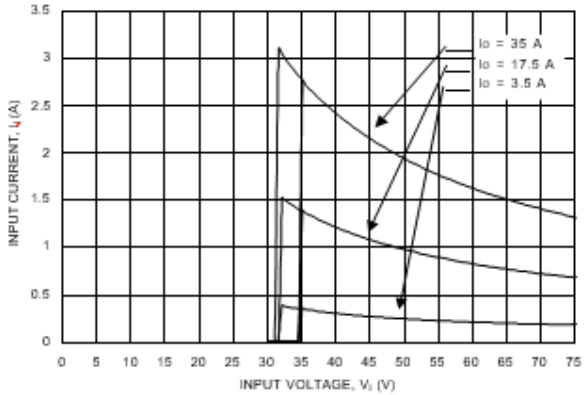


Figure 25. Input Voltage and Current Characteristics.

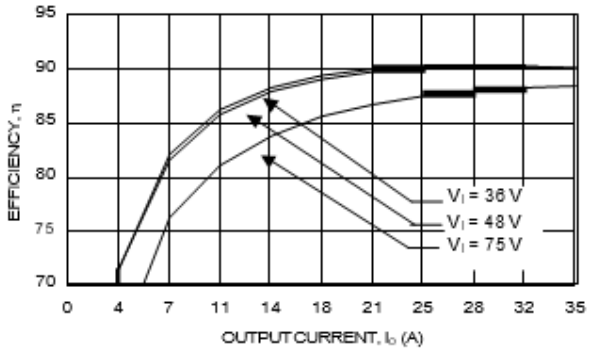


Figure 26. Converter Efficiency vs. Output Current.

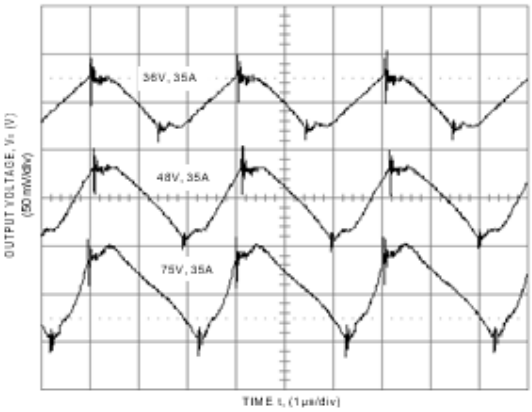
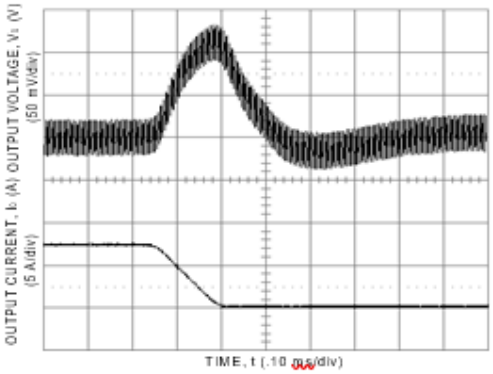


Figure 27. Output Ripple Voltage (IO = IO, max).



Tested with a 220µF aluminium and a 1.0µF ceramic capacitor across the load.

Figure 28. Transient Response to Step Decrease in Load from 50% to 25% of Full Load (VI = 48 Vdc).

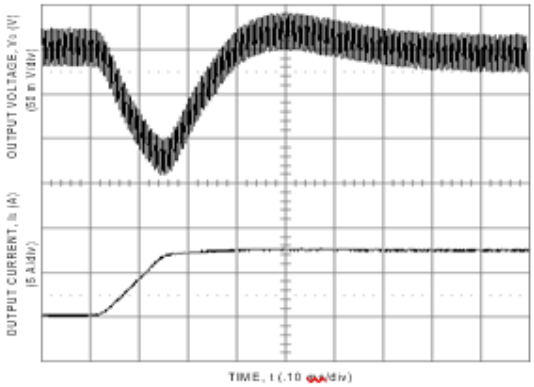
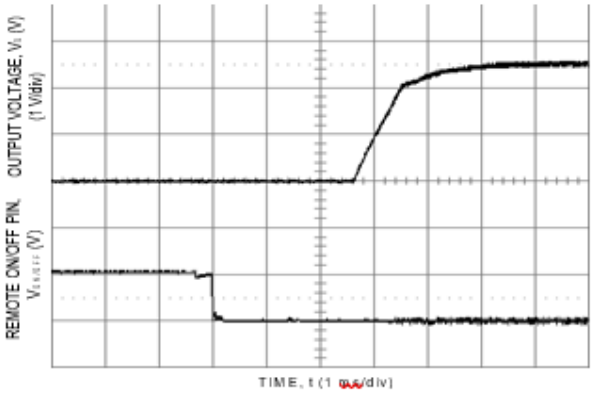


Figure 29. Transient Response to Step Increase in Load from 50% to 75% of Full Load (VI = 48 Vdc).



Tested with a 10µF aluminium and a 1.0µF tantalum capacitor across the load.

Figure 30. Start-up from Remote On/Off (IO = IO, max).

Electrical Specifications (continued)

Output Specifications for the QRW035A0F (Vo = 3.3Vdc)

Parameter	Device	Symbol	Min	Typ	Max	Unit
Output Voltage Set Point (VI = 48 Vdc; IO = IO, min to IO, max, TA = 25 °C)	F	Vo	3.24	3.3	3.36	Vdc
Output Voltage (Over all operating input voltage, resistive load, and temperature conditions at steady state until end of life.)	F	Vo	3.2	—	3.4	Vdc
Output Regulation: Line (VI = VI, min to VI, max) Load (IO = IO, min to IO, max) Temperature (TA = TA, min to TA, max)	F	 — — —	 — — —	 0.05 0.05 15	 0.2 0.2 50	 %, VO, set %, VO, set mV
Output Ripple and Noise RMS (5 Hz to 20 MHz bandwidth) Peak-to-peak (5 Hz to 20 MHz bandwidth)	F		 — —	 — —	 30 100	 mVrms mVp-p
External Load Capacitance				—	30,000	µF
Output Current (Vo =90% of VO, nom.)	F	IO	0.0	—	35	Adc
Output Current-limit Inception (VO = 90% of VO, set)	F	IO, lim	—	39	—	Adc
Output Short-circuit Current (Average)VO = 0.25 V	Latched off					
Efficiency (VI = VIN, nom; IO = IO, max), TA = 25 °C		η	—	91	—	%
Switching Frequency	All	fSW	—	300	—	kHz
Dynamic Response (DIO/Dt = 1 A/10 µs, VI = 48 V, TA = 25 °C); tested with a 220 µF aluminium and a 1.0 µf ceramic capacitor across the load.): Load Change from IO = 50% to 75% of IO, max: Peak Deviation Settling Time (VO < 10% of peak deviation) Load Change from IO = 50% to 25% of IO, max : Peak Deviation Settling Time (VO < 10% of peak deviation)				 160 300 160 300		 mV µs mV µs

Isolation Specifications

Parameter	Symbol	Min	Typ	Max	Unit
Isolation Capacitance	Ciso	—	5600	—	PF
Isolation Resistance	Riso	10	—	—	MΩ

General Specifications

Parameter	Min	Typ	Max	Unit
Calculated MTBF (Io = 80% of Io, max Ta = 40 °C), Issue 1, M1, C1		1,700,000		Hours
Weight	—	37(1.31)	—	g (oz.)

Feature Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

Parameter	Symbol	Min	Typ	Max	Unit
Remote On/Off Signal Interface* (VI = 0 V to 75 V; open collector or equivalent compatible; signal referenced to VI(–) terminal; see Figure 52 and Feature Descriptions.): Preferred Logic: Logic Low—Module OnLogic High—Module Off Optional Logic: Logic Low—Module OffLogic High—Module On Logic Low: At Ion/off = 1.0 mAAt Von/off = 0.0 V Logic High: At Ion/off = 0.0 µA Leakage Current Turn-on Time; see Typical Start-up Curve(IO = IO max; Vo within ±1% of steady state)	 Von/offIon/off Von/offIon/off	 0 — — —	 — — — —2	 1.2 1.0 15 50 4	 V mA V µAms
utput Voltage Adjustment (See Feature Descriptions): Output Voltage Remote-sense Range Output Voltage Set-point Adjustment Range (trim)	 — —	 — 80	 — —	 0.5 110	 V %V0,nom
Output Overvoltage Protection	VO, ovsd	3.8	—	4.6	V
Overtemperature Protection (IO = IO, max)	Tref1	—	127	—	°C

* A Minimum OFF Period of 1 sec is recommended.

Characteristic Curves

The following figures provide typical characteristics curves for the QRW035A0F (VO = 3.3 V) module at room temperature (TA = 25 °C)

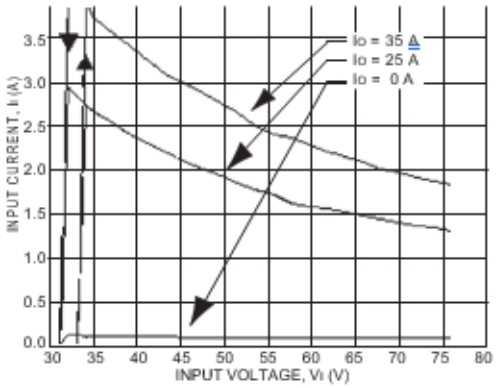


Figure 31. Input Voltage and Current Characteristics.

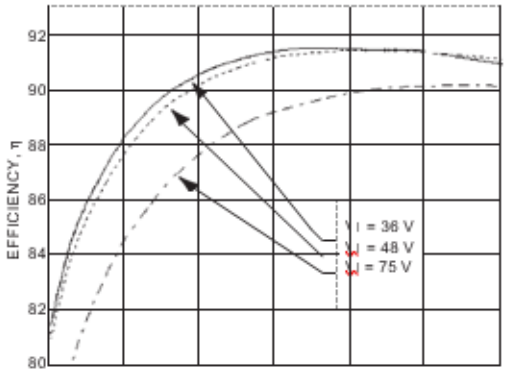


Figure 32. Converter Efficiency vs. Output Current.

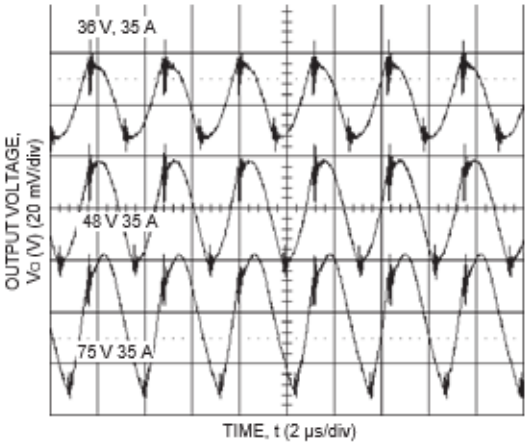
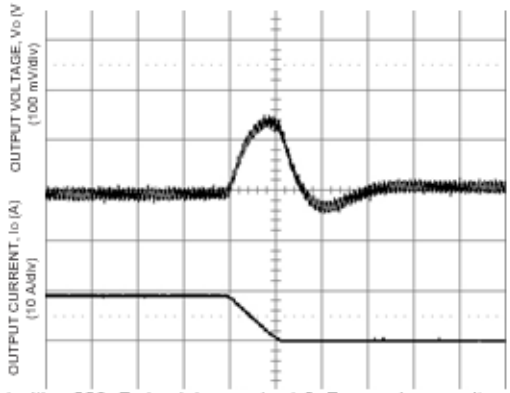


Figure 33. Output Ripple Voltage (IO = IO, max).



Tested with a 220μF aluminium and a 1.0μF ceramic capacitor across the load.

Figure 34. Transient Response to Step Decrease in Load from 50% to 25% of Full Load (VI = 48 Vdc).

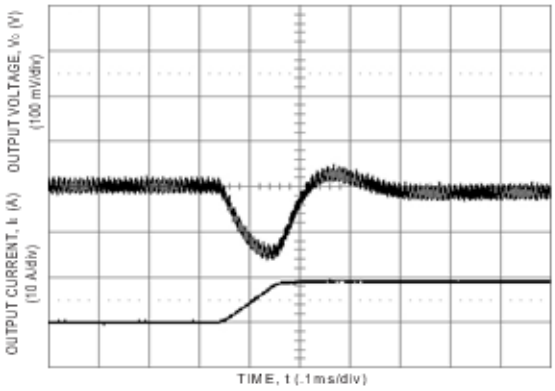
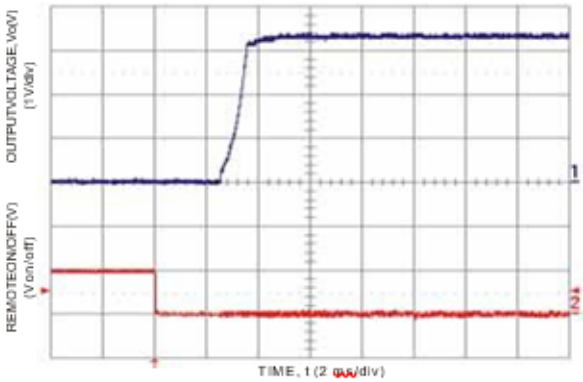


Figure 35. Transient Response to Step Increase in Load from 50% to 75% of Full Load (VI = 48 Vdc).



Tested with a 10μF aluminium and a 1.0μF tantalum capacitor across the load.

Figure 36. Start-up from Remote On/Off (IO = IO, max).

Electrical Specifications (continued)

Output Specifications for the QRW025A0A (Vo = 5.0 Vdc)

Parameter	Device	Symbol	Min	Typ	Max	Unit
Output Voltage Set Point (VI = 48 Vdc; IO = IO, min to IO, max, TA = 25 °C)	A	Vo	4.95	5.0	5.05	Vdc
Output Voltage (Over all operating input voltage, resistive load, and temperature conditions at steady state until end of life.)	A	Vo	4.85	—	5.15	Vdc
Output Regulation: Line (VI = VI, min to VI, max) Load (IO = IO, min to IO, max) Temperature (TA = TA, min to TA, max)	A	 — — —	 — — —	 0.05 0.05 15	 0.2 0.2 50	 %, VO, set %, VO, set mV
Output Ripple and Noise RMS (5 Hz to 20 MHz bandwidth) Peak-to-peak (5 Hz to 20 MHz bandwidth)	A		 — —	 — —	 30 100	 mVrms mVp-p
External Load Capacitance				—	10,000	µF
Output Current (Vo =90% of VO, nom.)	A	IO	0.0	—	25	Adc
Output Current-limit Inception (VO = 90% of VO, set)	A	IO, lim	—	30	—	Adc
Output Short-circuit Current (Average)VO = 0.25 V	Latched off					
Efficiency (VI = VIN, nom; IO = IO, max), TA = 25 °C		η	—	91.5	—	%
Switching Frequency	All	fSW	—	300	—	kHz
Dynamic Response (DIO/Dt = 1 A/10 µs, VI = 48 V, TA = 25 °C); tested with a 220 µF aluminium and a 1.0 µf ceramic capacitor across the load.): Load Change from IO = 50% to 75% of IO, max: Peak Deviation Settling Time (VO < 10% of peak deviation) Load Change from IO = 50% to 25% of IO, max : Peak Deviation Settling Time (VO < 10% of peak deviation)				 250 200 250 200		 mV µs mV µs

Isolation Specifications

Parameter	Symbol	Min	Typ	Max	Unit
Isolation Capacitance	Ciso	—	5600	—	PF
Isolation Resistance	Riso	10	—	—	MΩ

General Specifications

Parameter	Min	Typ	Max	Unit
Calculated MTBF (Io = 80% of Io, max Ta = 40 °C), Issue 1, M1,C1		1,219,777		Hours
Weight	—	37(1.31)	—	g (oz.)

Feature Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

Parameter	Symbol	Min	Typ	Max	Unit
Remote On/Off Signal Interface*					
(VI = 0 V to 75 V; open collector or equivalent compatible; signal referenced to VI(–) terminal; see Figure 52 and Feature Descriptions.):					
Preferred Logic:					
Logic Low—Module On					
Logic High—Module Off					
Optional Logic:					
Logic Low—Module Off					
Logic High—Module On					
Logic Low:					
At Ion/off = 1.0 mA					
At Von/off = 0.0 V	Von/off	0	—	1.2	V
Logic High:	Ion/off	—	—	1.0	mA
At Ion/off = 0.0 µA					
Leakage Current	Von/off	—	—	15	V
Turn-on Time; see Typical Start-up Curve(IO = IO max;	Ion/off	—	—	50	µA
Vo within ±1% of steady state)			1	4	ms
Output Voltage Adjustment					
(See Feature Descriptions):					
Output Voltage Remote-sense Range	—	—	—	0.5	V
Output Voltage Set-point Adjustment Range (trim)	—	80	—	110	%V0,nom
Output Overvoltage Protection	VO, ovsd	5.6	—	6.8	V
Overtemperature Protection (IO = IO, max)	Tref1	—	127	—	°C

* A Minimum OFF Period of 1 sec is recommended.

Characteristic Curves

The following figures provide typical characteristics curves for the QRW025A0A (VO = 5.0V) module at room temperature (TA = 25 °C)

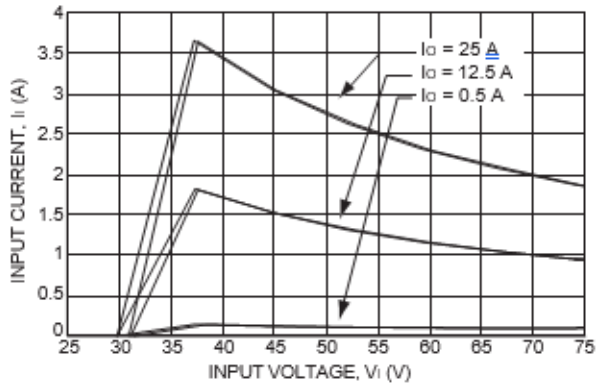


Figure 37. Input Voltage and Current Characteristics.

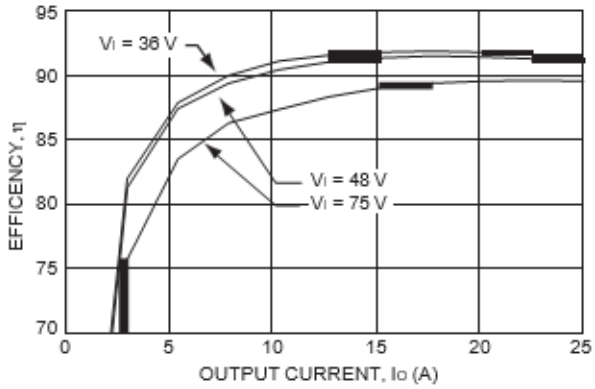


Figure 38. Converter Efficiency vs. Output Current.

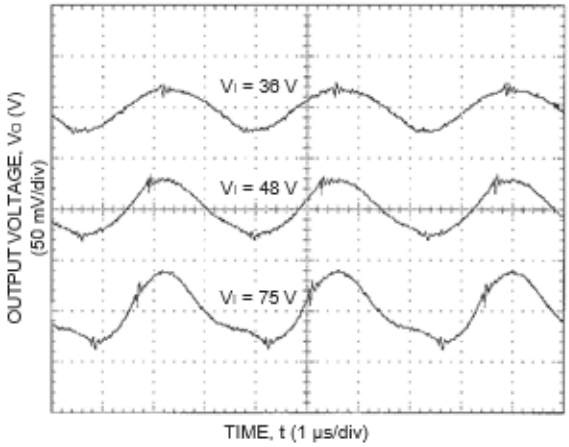
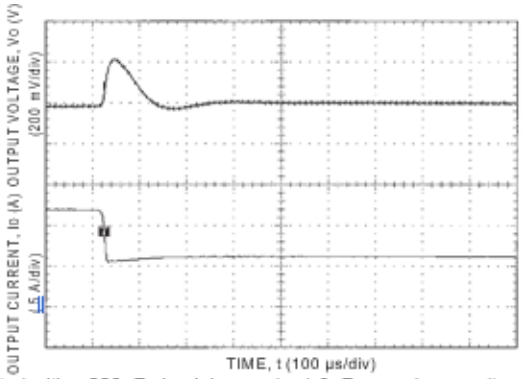


Figure 39. Output Ripple Voltage (IO = IO, max).



Tested with a 220µF aluminium and a 1.0µF ceramic capacitor across the load.

Figure 40. Transient Response to Step Decrease in Load from 50% to 25% of Full Load (VI = 48 Vdc).

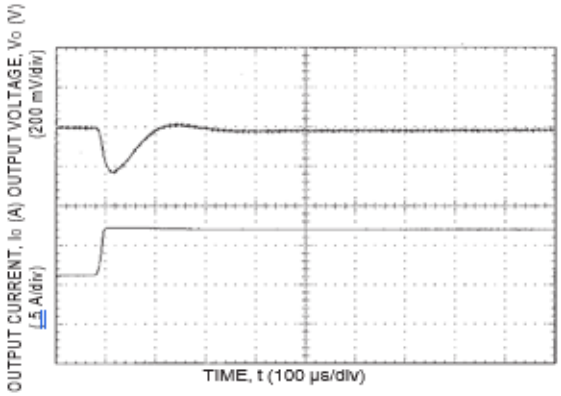
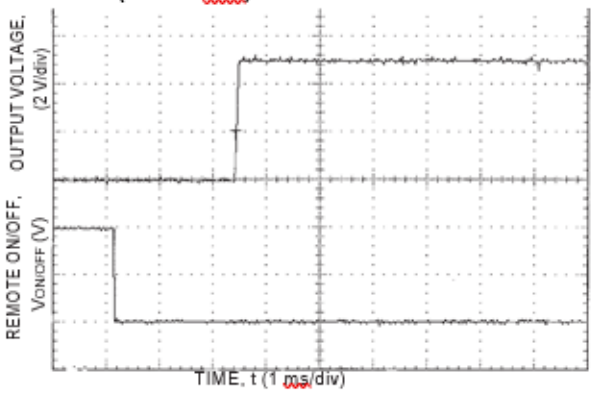


Figure 41. Transient Response to Step Increase in Load from 50% to 75% of Full Load (VI = 48 Vdc).



Tested with a 10µF aluminium and a 1.0µF tantalum capacitor across the load.

Figure 42. Start-up from Remote On/Off (IO = IO, max).

Electrical Specifications (continued)

Output Specifications for the QRW010A0B (Vo = 12.0 Vdc)

Parameter	Device	Symbol	Min	Typ	Max	Unit
Output Voltage Set Point (VI = 48 Vdc; IO = IO, min to IO, max, TA = 25 °C)	B	Vo	11.76	12	12.24	Vdc
Output Voltage (Over all operating input voltage, resistive load, and temperature conditions at steady state until end of life.)	B	Vo	11.64	—	12.36	Vdc
Output Regulation: Line (VI = VI, min to VI, max) Load (IO = IO, min to IO, max) Temperature (TA = TA, min to TA, max)	B	 — — —	 — — —	 0.05 0.05 15	 0.2 0.2 50	 %, VO, set %, VO, set mV
Output Ripple and Noise RMS (5 Hz to 20 MHz bandwidth) Peak-to-peak (5 Hz to 20 MHz bandwidth)	B		 — —	 — —	 30 100	 mVrms mVp-p
External Load Capacitance				—	2200	µF
Output Current (Vo =90% of VO, nom.)	B	IO	0.0	—	10	Adc
Output Current-limit Inception (VO = 90% of VO, set)	B	IO, lim	—	12	—	Adc
Output Short-circuit Current (Average)VO = 0.25 V	Latched off					
Efficiency (VI = VIN, nom; IO = IO, max), TA = 25 °C		η	—	92.5	—	%
Switching Frequency	All	fSW	—	300	—	kHz
Dynamic Response (DIO/Dt = 1 A/10 µs, VI = 48 V, TA = 25 °C); tested with a 220 µF aluminium and a 1.0 µf ceramic capacitor across the load.): Load Change from IO = 50% to 75% of IO, max: Peak Deviation Settling Time (VO < 10% of peak deviation) Load Change from IO = 50% to 25% of IO, max : Peak Deviation Settling Time (VO < 10% of peak deviation)				 360 300 360 300		 mV µs mV µs

Isolation Specifications

Parameter	Symbol	Min	Typ	Max	Unit
Isolation Capacitance	Ciso	—	5600	—	PF
Isolation Resistance	Riso	10	—	—	MΩ

General Specifications

Parameter	Min	Typ	Max	Unit
Calculated MTBF (Io = 80% of Io, max, Ta = 40 °C), Issue 1, M1,C1		1,227,000		Hours
Weight	—	37(1.31)	—	g (oz.)

Feature Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

Parameter	Symbol	Min	Typ	Max	Unit
Remote On/Off Signal Interface*					
(VI = 0 V to 75 V; open collector or equivalent compatible; signal referenced to VI(–) terminal; see Figure 52 and Feature Descriptions.):					
Preferred Logic:					
Logic Low—Module On					
Logic High—Module Off					
Optional Logic:					
Logic Low—Module Off					
Logic High—Module On					
Logic Low:					
At Ion/off = 1.0 mA					
At Von/off = 0.0 V	Von/off	0	—	1.2	V
Logic High:	Ion/off	—	—	1.0	mA
At Ion/off = 0.0 µA					
Leakage Current	Von/off	—	—	15	V
Turn-on Time; see Typical Start-up Curve(IO = IO max;	Ion/off	—	—	50	µA
Vo within ±1% of steady state)			2	4	ms
Output Voltage Adjustment (See Feature Descriptions):					
Output Voltage Remote-sense Range	—	—	—	0.5	V
Output Voltage Set-point Adjustment Range (trim)	—	80	—	110	%V0,nom
Output Overvoltage Protection	VO, ovsd	13.5	15	16.5	V
Overtemperature Protection (IO = IO, max)	Tref1	—	127	—	°C

* A Minimum OFF Period of 1 sec is recommended.

Characteristic Curves

The following figures provide typical characteristics curves for the QRW010A0B (VO = 12.0V) module at room temperature (TA = 25 °C)

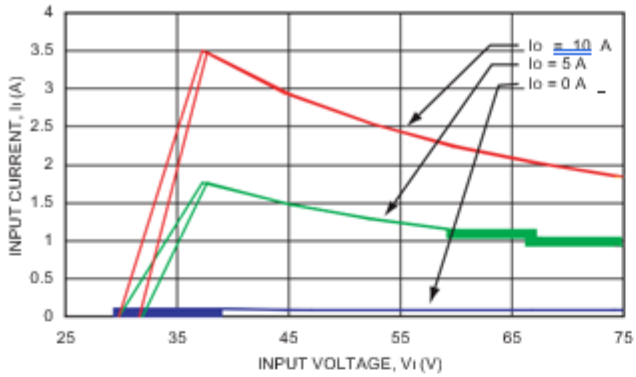


Figure 43. Input Voltage and Current Characteristics.

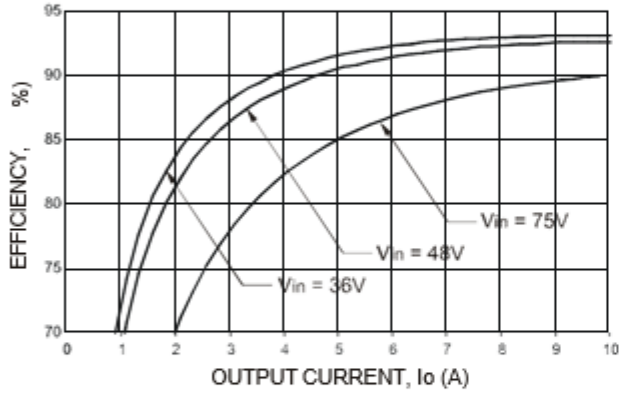


Figure 44. Converter Efficiency vs. Output Current.

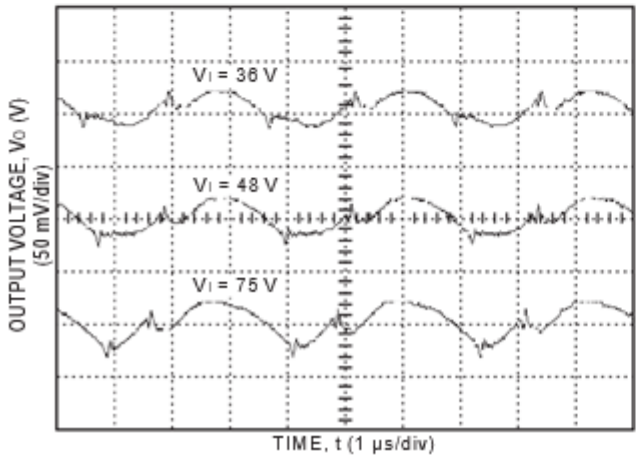
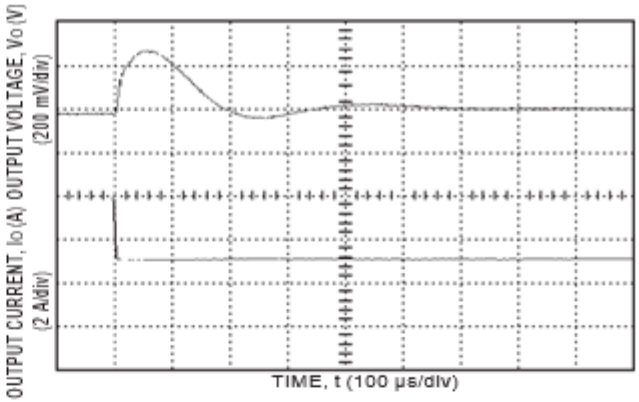


Figure 45. Output Ripple Voltage (IO = IO, max).



Tested with a 220µF aluminium and a 1.0µF ceramic capacitor across the load.

Figure 46. Transient Response to Step Decrease in Load from 50% to 25% of Full Load (VI = 48 Vdc).

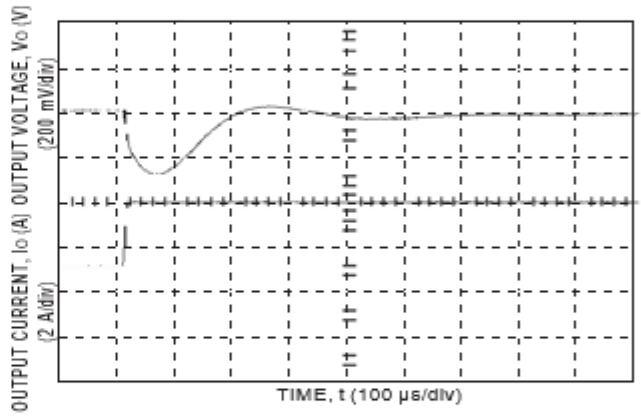
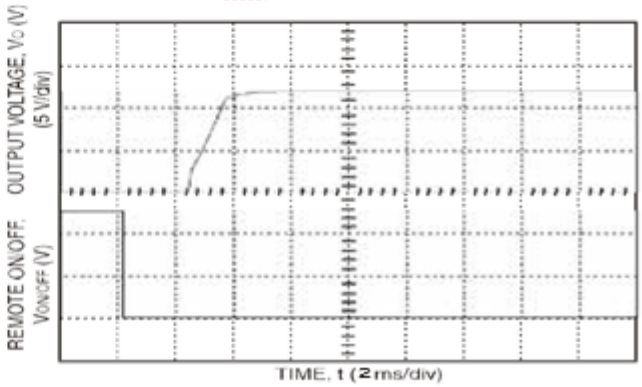


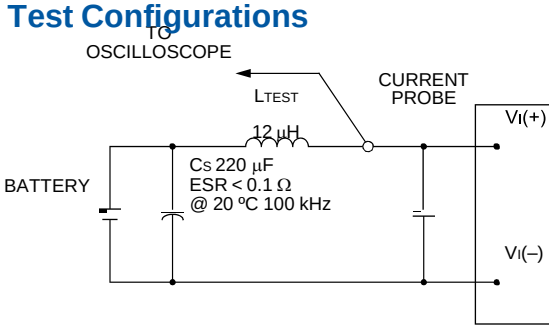
Figure 47. Transient Response to Step Increase in Load from 50% to 75% of Full Load (VI = 48 Vdc).



Tested with a 10µF aluminium and a 1.0µF tantalum capacitor across the load.

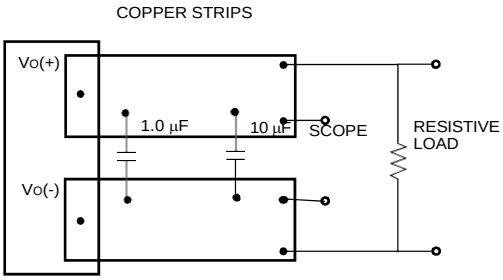
Figure 48. Start-up from Remote On/Off (IO = IO, max).

Test Configurations



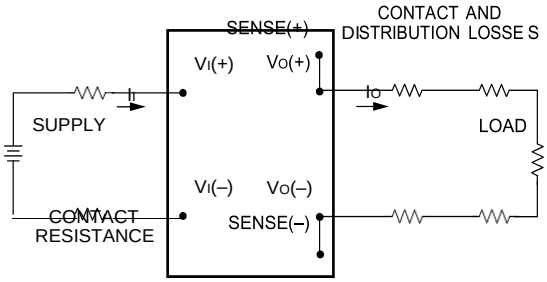
Note: Measure input reflected-ripple current with a simulated source inductance (LTEST) of 12 µH. Capacitor CS offsets possible battery impedance. Measure current as shown above.

Figure 49. Input Reflected-Ripple Test Setup.



Note: Use a 1.0 µF ceramic capacitor and a 10 µF aluminum or tantalum capacitor. Scope measurement should be made using a BNC socket. Position the load between 51 mm and 76 mm (2 in. and 3 in.) from the module.

Figure 50. Peak-to-Peak Output Noise Measurement Test Setup.



Note: All measurements are taken at the module terminals. When socketing, place Kelvin connections at module terminals to avoid measurement errors due to socket contact resistance.

$$\left(\frac{[V_O(+) - V_O(-)]I_O}{[V_I(+) - V_I(-)]I_I} \right) \times 100\ \%$$

Design Considerations

Input Source Impedance

The power module should be connected to a low ac-impedance input source. Highly inductive source impedances can affect the stability of the power module. For the test configuration in 49, a 33 µF electrolytic capacitor (ESR < 0.7 W at 100 kHz) mounted close to the power module helps ensure stability of the unit. For other highly inductive source impedances, consult the factory for further application guidelines.

Output Capacitance

High output current transient rate of change (high di/dt) loads may require high values of output capacitance to supply the instantaneous energy requirement to the load. Tp minimize the output voltage transient drop during this transient, low E.S.R. (equivalent series resistance) capacitors may be required, since a high E.S.R. will produce a correspondingly higher voltage drop during the current transient.

Output capacitance and load impedance interact with the power module's output voltage regulation control system and may produce an 'unstable' output condition for the required values of capacitance and E.S.R.. Minimum and maximum values of output capacitance and of the capacitor's associ-

ated E.S.R. may be dictated, depending on the module's con-trol system.

The process of determining the acceptable valuesof capacitance and E.S.R. is complex and is load-dependant. Lineage provides Web-based tools to assistthe power module end-user in appraising and adjusting the effect of various load conditions and output capacitances on specific power modules for various load conditions.

Safety Considerations

For safety-agency approval of the system in which the powermodule is used, the power module must be installed in com-pliance with the spacing and separation requirements of the end-use safety agency standard, i.e., UL62368-1, CSA C22.2 No. 62368-1, and VDE 0868-1/A11 (IEC62368, 2nd Ed).

These converters have been evaluated to the spacing requirements for Basic Insulation, per the above safety stan-dards and 1500 Vdc is applied from VI to VO to 100% of out-going production.

For end products connected to –48 Vdc, or –60 Vdc nomianl DC MAINS (i.e. central office dc battery plant), no further fault testing is required.

Note:–60 V dc nominal bettery plants are not available in the U.S. or Canada.

For all input voltages, other than DC MAINS, where the input voltage is less than 60 Vdc, if the input meets all of the requirements for SELV/ES1, then:

Figure 51. Output Voltage and Efficiency Measurement.

- The output may be considered SELV/ES1. Output voltages willremain withing SELV /ES1 limits even with internally-generatednon-SELV voltages. Single component failure and fault tests were performed in the power converters.
- One pole of the input and one pole of the output are to be grounded, or both circuits are to be kept floating, to maintain the output voltage to ground voltage within ELV or SELV/ES1 limits.

For all input sources, other than DC MAINS, where the input voltage is between 60 and 75 Vdc (Classified as TNV-2 in Europe), the following must be adhered to, if the converter's output is to be evaluated for SELV/ES1:

- The input source is to be provided with reinforced insulation from any hazardous voltage, including the AC mains.
- One VI pin and one VO pin are to be reliably earthed, or both the input and output pins are to be kept floating.

- Another SELV or ES1 reliability test is conducted on the whole system (combination of supply source and subject module), as required by the safety agencies, to verify that under a single fault, hazardous voltages do not appear at the module's output.

The power module has safety extra-low voltage (SELV) or ES1 outputs when all inputs are SELV or ES1.

All flammable materials used in the manufacturing of these modules are rated 94V-0, and UL62368A.2 for reduced thicknesses. The input to these units is to be provided with a maximum 10A normal-blow fuse in the ungrounded lead.

Feature Descriptions

Overcurrent Protection

To provide protection in a fault output overload condition, the module is equipped with internal current-limiting circuitry and can endure current limit for few seconds. If overcurrent persists for few seconds, the module will shut down and remain latch-off.

The overcurrent latch is reset by either cycling the input power or by toggling the on/off pin for one second. If the output overload condition still exists when the module restarts, it will shut down again. This operation will continue indefinitely until the overcurrent condition is corrected.

An auto-restart option is also available.

Remote On/Off

Two remote on/off options are available. Positive logic remote on/off turns the module on during a logic-high voltage on the ON/OFF pin, and off during a logic low. Negative logic remote on/off turns the module off during a logic high and on during a logic low. Negative logic, device code suffix "1," is the factory-preferred configuration.

To turn the power module on and off, the user must supply a switch to control the voltage between the on/off terminal and the VI(-) terminal (Von/off). The switch can be an open collector or equivalent (see Figure 10). A logic low is Von/off = 0 V to I.2 V. The maximum Ion/off during a logic low is 1 mA. The switch should maintain a logic-low voltage while sinking 1 mA.

During a logic high, the maximum Von/off generated by the power module is 15 V. The maximum allowable leakage current of the switch at Von/off = 15V is 50 µA.

If not using the remote on/off feature, do one of the following to turn the unit on

For negative logic, short ON/OFF pin to VI(-).
For positive logic: leave ON/OFF pin open.

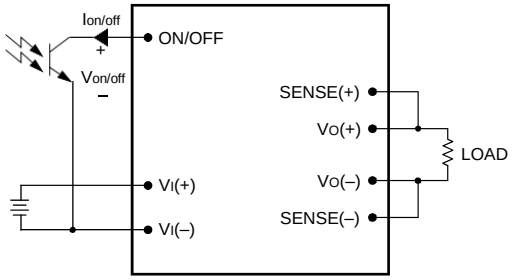


Figure 52. Remote On/Off Implementation.

Remote Sense

Remote sense minimizes the effects of distribution losses by regulating the voltage at the remote-sense connections. The voltage between the remote-sense pins and the output terminals must not exceed the output voltage sense range given in

the Feature Specifications table i.e.:

[Vo(+) – Vo(-)] – [SENSE(+) – SENSE(-)] £ 10% of Vo, rated

The voltage between the Vo(+) and Vo(-) terminals must not exceed the minimum output overvoltage shutdown value indi-cated in the Feature Specifications table. This limit includes any increase in voltage due to remote-sense compensation and output voltage set-point adjustment (trim). See Figure 53.

If not using the remote-sense feature to regulate the output atthe point of load, then connect SENSE(+) to Vo(+) and SENSE(-) to Vo(-) at the module.

Although the output voltage can be increased by both the remote sense and by tine trim, the maximum increase for theoutput voltage is not the sum of both. The maximum increaseis the larger of either the remote sense or the trim.

The amount of power delivered by the module is defined as the voltage at the output terminals multiplied by the output current. When using remote sense and trim: the output volt- age of the module can be increased, which at the same out-put current would increase the power output of the module. Care should be taken to ensure that the maximum output power of the module remains at or below the maximum ratedpower.

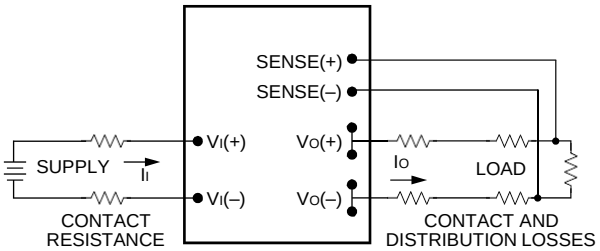


Figure 53. Effective Circuit Configuration for Single-Module Remote-Sense OperationOutput Voltage.

Output Overvoltage Protection

The output overvoltage protection consists of circuitry that monitors the voltage on the output terminals. If the voltage onthe output terminals exceeds the over voltage protection threshold, then the module will shutdown and latch off. The overvoltage latch is reset by either cycling the input power for one second or by togglingthe on/off signal for one second.

The protection mechanism is such that the unit can continuein this condition until the fault is cleared.

Overtemperature Protection

These modules feature an overtemperature protection circuitto safeguard against thermal damage. The circuit shuts downand latches off the module when the maximum device refer-ence temperature is exceeded. The module can be restartedby cycling the dc input power for at least one second or by toggling the remote on/off signal for at least one second.

Feature Descriptions (Continued)

Output Voltage Set-Point Adjustment (Trim)

Trimming allows the user to increase or decrease the output voltage set point of a module. This is accomplished by connecting an external resistor between the TRIM pin and either the SENSE(+) or SENSE(-) pins. The trim resistor should be positioned close to the module.

If not using the trim feature, leave the TRIM pin open.

With an external resistor between the TRIM and SENSE(-) pins (Radj-down), the output voltage set point (Vo adj) decreases (see Figure 54). The following equation determines the required external-resistor value to obtain a percentage output voltage change of D%.

For Output Voltage: 1.0V - 12V

$$R_{adj\text{-}down} = \left[\frac{510}{\Delta\%} - 10.2\right] k\Omega$$

With an external resistor connected between the TRIM and SENSE(+) pins (Radj-up), the output voltage set point (Vo adj) increases (see Figure 55).

The following equation determines the required external-resistor value to obtain a percentage output voltage change of D%

For Output Voltage: 1.5V - 12V

$$R_{adj\text{-}up} = \left[\frac{5.1 \cdot Vo \cdot (100 + \Delta\%)}{1.225\ \Delta\%} - \frac{510}{\Delta\%} - 10.2\right] k\Omega$$

For Output Voltage: 1.2V, 1.0V

$$R_{adj\text{-}up} = \left[\frac{5.1\ Vo\ (100 + \Delta\%)}{0.6\ \Delta\%} - \frac{510}{\Delta\%} - 10.2\right] k\Omega$$

The voltage between the Vo(+) and Vo(-) terminals must not exceed the minimum output overvoltage shut-down value indicated in the Feature Specifications table. This limit includes any increase in voltage due to remote-sense compensation and output voltage set-point adjustment (trim). See Figure 53.

Although the output voltage can be increased by both the remote sense and by the trim, the maximum increase for the output voltage is not the sum of both. The maximum increase is the larger of either the remote sense or the trim.

The amount of power delivered by the module is defined as the voltage at the output terminals multiplied by the output current. When using remote sense and trim, the output voltage of the module can be increased, which at the same output current would increase the power output of the module. Care should be taken to ensure that the maximum output power of the module remains at or below the maximum rated power.

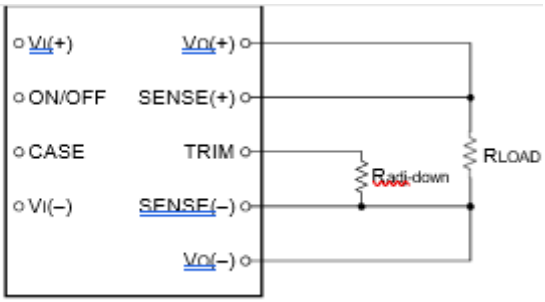


Figure 54. Circuit Configuration to Decrease Output Voltage.

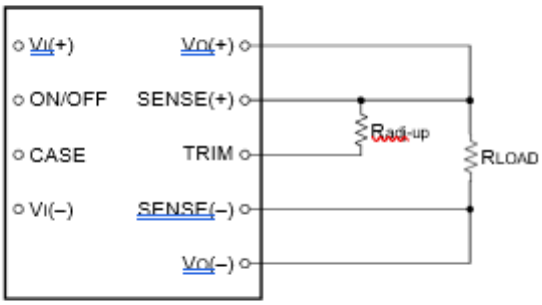
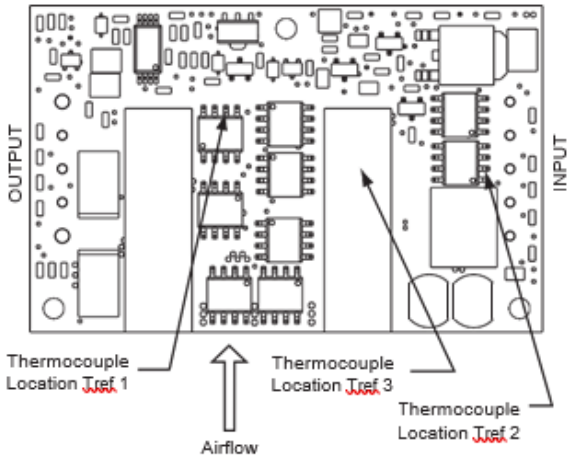


Figure 55. Circuit Configuration to Increase Output Voltage.

Thermal Considerations

The power modules operate in a variety of thermal environments; however, sufficient cooling should be provided to help ensure reliable operation of the unit. Heat-dissipating components are mounted on the top side of the module. Heat is removed by conduction, convection and radiation to the surrounding environment. Proper cooling can be verified by measuring the temperature of selected components on the topside of the power module (See 56). Peak temperature (Tref) can occur at any of these positions indicated in Figure 50.



Note:Top view, pin locations are for reference only.

Figure 56. Temperature Measurement Location.

The temperature at any one of these locations should not exceed per 1 to ensure reliable operation of the power module. The output power of the module should not exceed the rated power for the module as listed in the Ordering Information table.

Although the maximum Tref temperature of the power modules is per 1, you can limit these temperatures to a lower value for extremely high reliability.

Table 1. Device Temperature

Output Voltage	Device	Temperature (°C)
1.0V	Tref1	116
1.2V	Tref1	119
1.5V	Tref1	118
1.8V	Tref1	117
2.5V	Tref1	118
3.3V	Tref1	114
	Tref2	112
	Tref3	130
5V	Tref1	113
12V	Tref1	118

Heat Transfer Without Heat Sinks

Increasing airflow over the module enhances the heat transfer via convection. Figures 57 through 64 shows the maximum current that can be delivered by the corresponding module without exceeding the maximum case temperature versus local ambient temperature (TA) for natural convection through 2 m/s (400 ft./min.).

Note that the natural convection condition was measured at 0.05 m/s to 0.1 m/s (10ft./min. to 20 ft./min.); however, systems in which these power modules may be used typically generate natural convection airflow rates of 0.3 m/s (60 ft./min.) due to other heat dissipating components in the system. The use of output power derating curve is shown in the following example.

What is the minimum airflow necessary for a QRW035A0F operating at VI = 48 V, an output current of 23A, and a maximum ambient temperature of 70 °C.

Solution

Given: VI = 48V

Io = 23A

TA = 70 °C

Determine airflow (v) (Use Figure 62):

v = 1m/sec. (200ft./min.)

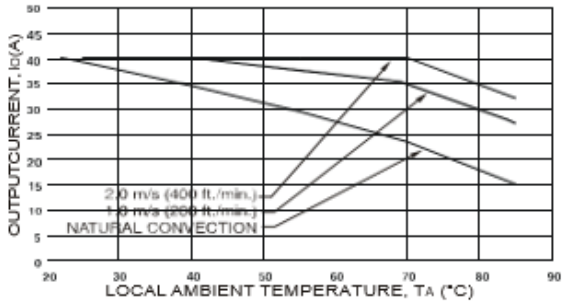


Figure 57. Output Power Derating for QRW040A0S1R0 (Vo = 1.0V) in Transverse Orientation with No Baseplate; Airflow direction from VIN (+) to VIN (–); VIN = 48V.

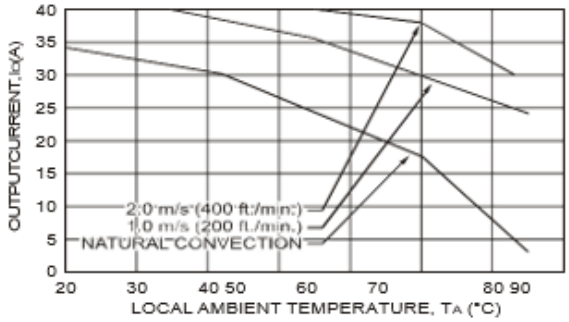


Figure 58. Output Power Derating for QRW040A0P (Vo = 1.2V) in Transverse Orientation with No Baseplate; Airflow direction from VIN (+) to VIN (–); VIN = 48V.

Thermal Considerations (continued)

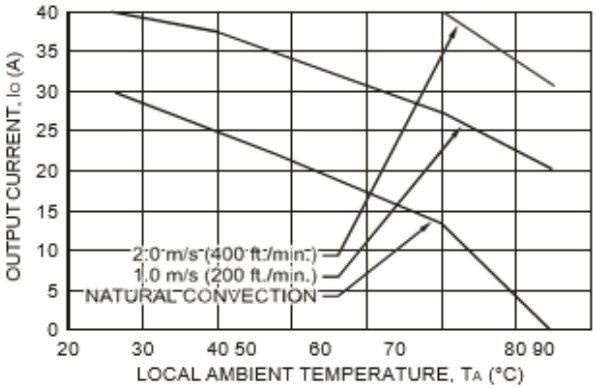


Figure 59. Output Power Derating for QRW040A0M (Vo = 1.5V) in Transverse Orientation with No Baseplate; Airflow direction from VIN (+) to VIN (–); VIN = 48V.

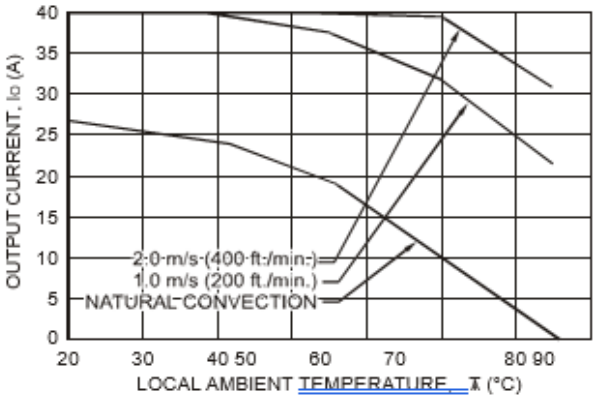


Figure 60. Output Power Derating for QRW040A0Y (Vo = 1.8V) in Transverse Orientation with No Baseplate; Airflow direction from VIN (+) to VIN (–); VIN = 48V.

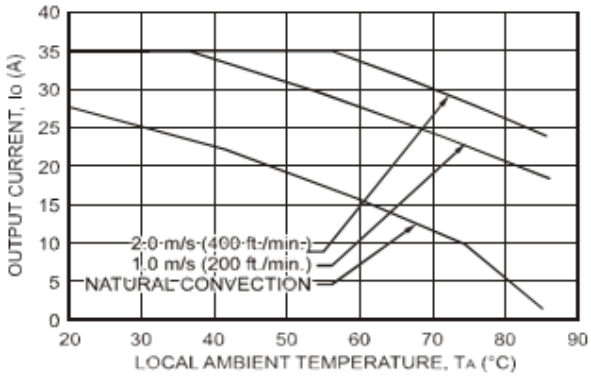


Figure 61. Output Power Derating for QRW0350G (Vo = 2.5) in Transverse Orientation with No Baseplate; Airflow direction from VIN (+) to VIN (–); VIN = 48V.

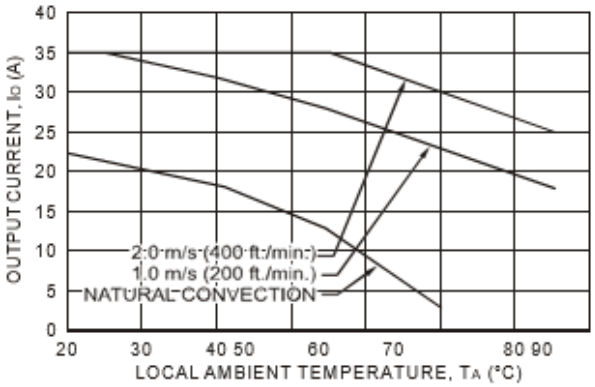


Figure 62. Output Power Derating for QRW035A0F (Vo = 3.3V) in Transverse Orientation with No Baseplate; Airflow direction from VIN (+) to VIN (–); VIN = 48V.

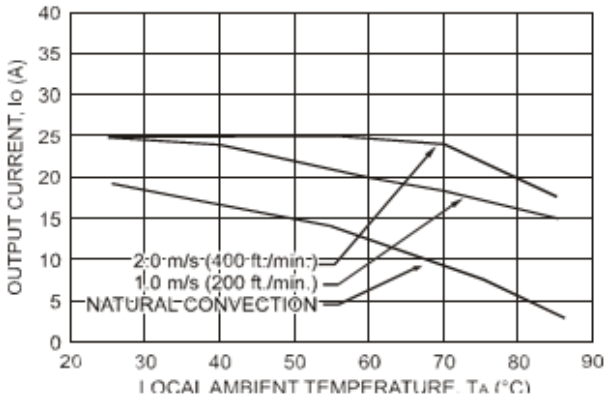


Figure 63. Output Power Derating for QRW025A0A (Vo = 5V) in Transverse Orientation with No Baseplate; Airflow direction from VIN (+) to VIN (–); VIN = 48V.

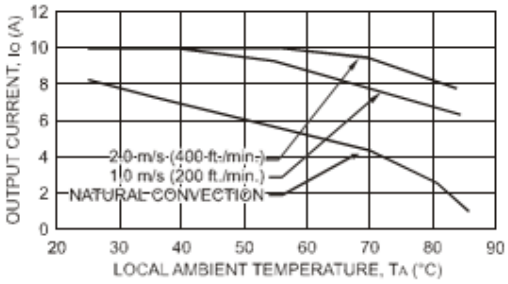
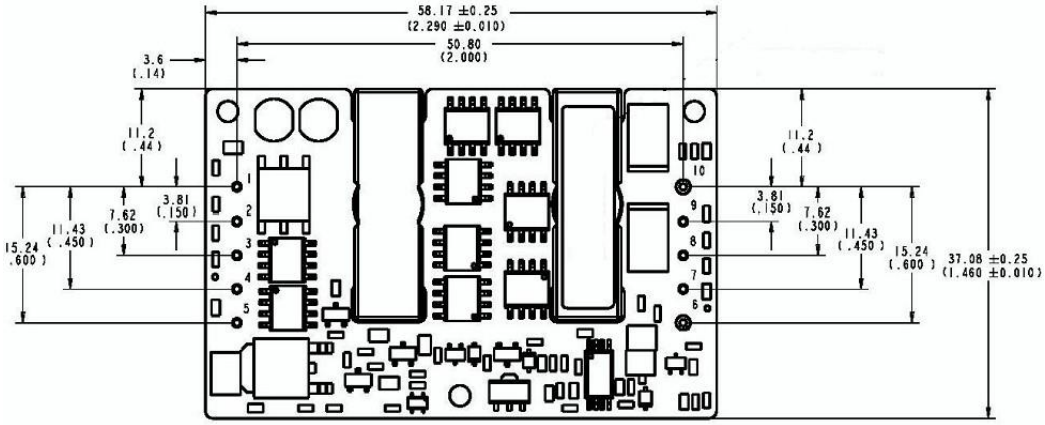


Figure 64. Output Power Derating for QRW010A0B (Vo = 12V) in Transverse Orientation with No Baseplate; Airflow direction from VIN (+) to VIN (–); VIN = 48V.

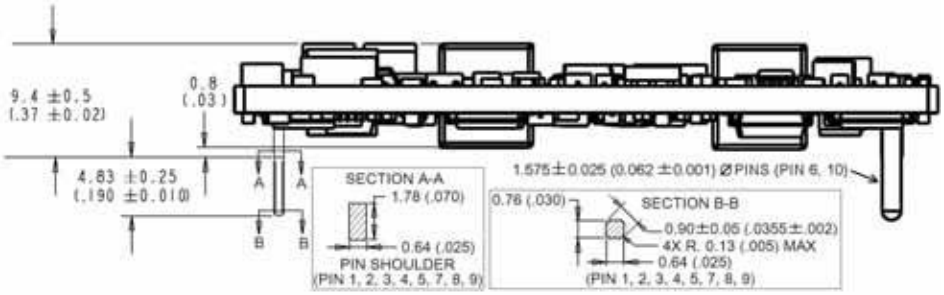
Outline Diagram

Dimensions are in millimeters and (inches)
Tolerences: x.x mm 0.5 mm (x.xx in. 0.02 in.)
x.xx mm 0.25 mm (x.xxx in. 0.010 in.)

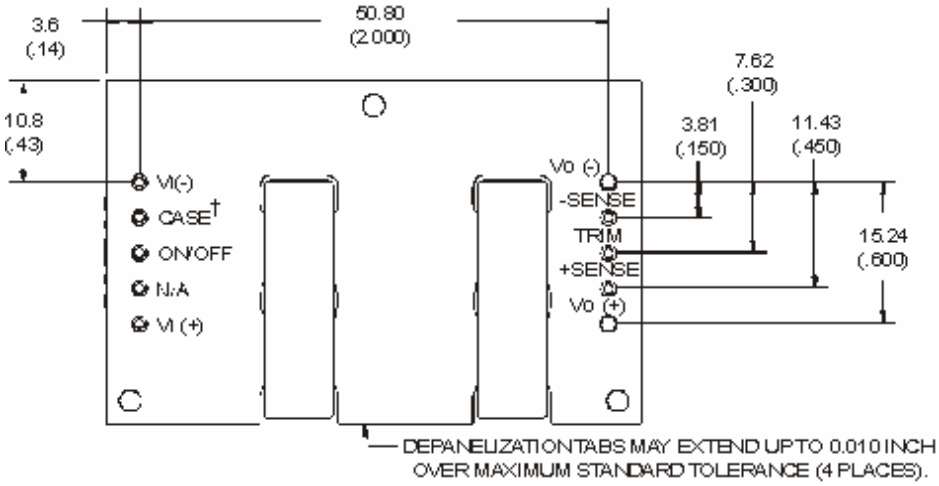
Top View



Side View



Bottom View

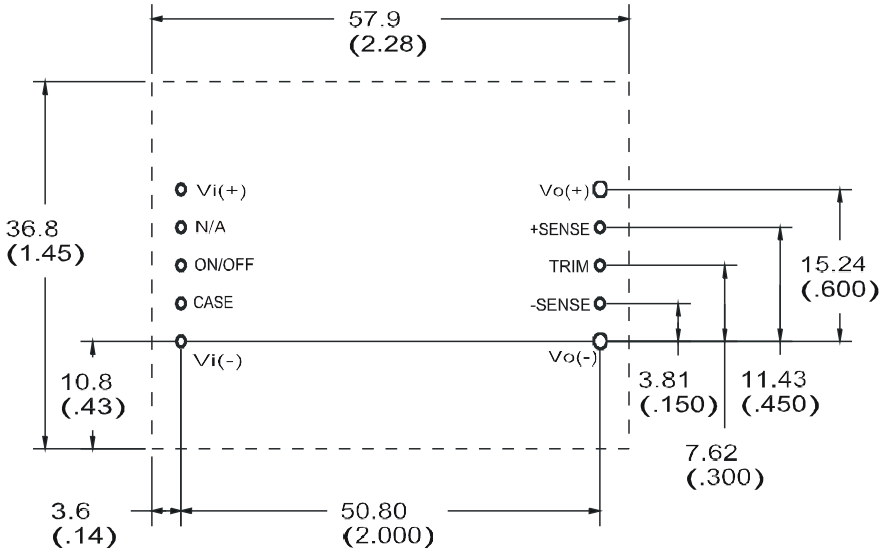


1-0454

*Top Side label includes Lineage name, product designation, and data code.
†Optional Features, Pin is not present unless one of these options is specified.

Recommended Hole Pattern

Dimensions are in millimeters and (inches).



Name	Pin No.	Function
Vi(+)	1	Positive input voltage
N/A	2	
ON/OFF	3	Remote On/Off signal
CASE*	4	Connected to base plate
Vi(-)	5	Negative input voltage
Vo(-)	6	Negative output voltage
-SENSE	7	Negative remote sense
TRIM	8	Output voltage trim
+SENSE	9	Positive remote sense
Vo(+)	10	Positive output voltage

* CASE pin only available on -H option modules.

Through-Hole Lead-Free Soldering Information

The RoHS-compliant through-hole products use the SAC (Sn/Ag/Cu) Pb-free solder and RoHS-compliant components. They are designed to be processed through single or dual wave soldering machines. The pins have an RoHS-compliant finish that is compatible with both Pb and Pb-free wave soldering processes. A maximum preheat rate of 3°C/s is suggested. The wave preheat process should be such that the temperature of the power module board is kept below 210°C. For Pb solder, the recommended pot temperature is 260°C, while the Pb-free solder pot is 270°C max. Not all RoHS-compliant through-hole products can be processed with paste-through-hole Pb or Pb-free reflow process. If additional information is needed, please consult with your Lineage Power System representative for more details.

Post Solder Cleaning and Drying Considerations

Post solder cleaning is usually the final circuit-board assembly process prior to electrical board testing. The result of inadequate cleaning and drying can affect both the reliability of a power module and the testability of the finished circuit-board assembly. For guidance on appropriate soldering, cleaning and drying procedures, refer to Lineage Power *Board Mounted Power Modules: Soldering and Cleaning* Application Note (AP01-056EPS).

Ordering Information

Please contact your Lineage Power Sales Representative for pricing, availability and optional features.

Table 1. Product Codes

Input Voltage	Output Voltage	Output Current	Efficiency	Connector Type	Product Codes	Comcodes
48V (36-75Vdc)	12V	10A	91%	Through hole	QRW010A0B1Z	CC109102992
48V (36-75Vdc)	12V	10A	91%	Through hole	QRW010A0B41-HZ	CC109143228
48V (36-75Vdc)	5.0V	25A	92%	Through hole	QRW025A0A1Z	CC109101474
48V (36-75Vdc)	5.0V	25A	92%	Through hole	QRW025A0A6Z	CC109142675
48V (36-75Vdc)	5.0V	25A	92%	Through hole	QRW025A0A41Z	CC109127214
48V (36-75Vdc)	5.0V	25A	92%	Through hole	QRW025A0A641Z	CC109143211
48V (36-75Vdc)	5.0V	25A	92%	Through hole	QRW025A0A1-HZ	CC109120755
48V (36-75Vdc)	5.0V	25A	92%	Through hole	QRW025A0A741-HZ	CC109114204
48V (36-75Vdc)	3.3V	35A	91%	Through hole	QRW035A0F1Z	108995230
48V (36-75Vdc)	3.3V	35A	91%	Through hole	QRW035A0F1-HZ	CC109144440
48V (36-75Vdc)	3.3V	35A	91%	Through hole	QRW035A0F41Z	CC109107612
48V (36-75Vdc)	3.3V	35A	91%	Through hole	QRW035A0F641Z	CC109138970
48V (36-75Vdc)	3.3V	35A	91%	Through hole	QRW035A0F741-HZ	CC109114212

QRW010/025/035/040; DC-DC Converter Power Modules

36-75Vdc Input; 1.0 to 12.0Vdc, 10A to 40A Output

Table 2. Device Options

	Characteristic	Character and Position	Definition
Ratings	Form Factor	Q	Q = Quarter Brick
	Family Designator	R	Family Designator
	Input Voltage	W	W = Wide Range, 36V-75V
	Output Current	035A0	035A0 = 035.0 Amps Maximum Output Current
	Output Voltage	B A F G Y M P S	B = 12V nominal A = 5.0V nominal F = 3.3V nominal G = 2.5V nominal Y = 1.8V nominal M = 1.5V nominal P = 1.2V nominal S = 1.0V nominal
	Pin Length	8 7 6	Omit = Default Pin Length shown in Mechanical Outline Figures 8 = Pin Length: 2.79 mm ± 0.25mm , (0.110 in. ± 0.010 in.) 7 = Case Pin (only available with H option) 6 = Pin Length: 3.68 mm ± 0.25mm , (0.145 in. ± 0.010 in.)
	Action following Protective Shutdown	4	Omit = Latching Mode 4 = Auto-restart following shutdown (Overcurrent/Overvoltage)
	On/Off Logic	1	Omit = Positive Logic 1 = Negative Logic
		-	
	Mechanical Features	H	Omit = Standard open Frame Module H = Heat plate, for use with heat sinks or cold-walls
	Customer Specific	XY	XY = Customer Specific Modified Code, Omit for Standard Code
	RoHS	Z	Omit = RoHS 5/6, Lead Based Solder Used Z = RoHS 6/6 Compliant, Lead free

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